

# TLV2211, TLV2211Y

## Advanced LinCMOS™ RAIL-TO-RAIL

### MICROPOWER SINGLE OPERATIONAL AMPLIFIERS

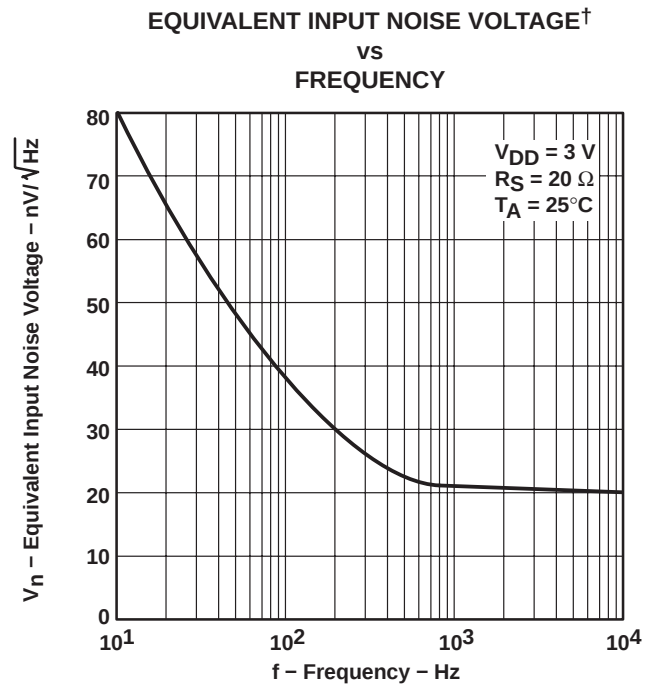
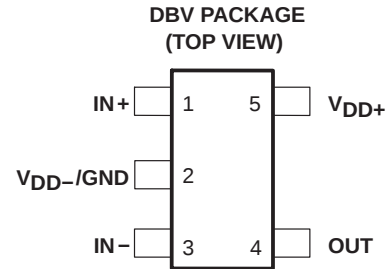
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- Output Swing Includes Both Supply Rails
- Low Noise . . . 21 nV/√Hz Typ at f = 1 kHz
- Low Input Bias Current . . . 1 pA Typ
- Very Low Power . . . 11 μA Per Channel Typ
- Common-Mode Input Voltage Range Includes Negative Rail
- Wide Supply Voltage Range 2.7 V to 10 V
- Available in the SOT-23 Package
- Macromodel Included

#### description

The TLV2211 is a single low-voltage operational amplifier available in the SOT-23 package. It consumes only 11 μA (typ) of supply current and is ideal for battery-power applications. Looking at Figure 1, the TLV2211 has a 3-V noise level of 22 nV/√Hz at 1kHz; 5 times lower than competitive SOT-23 micropower solutions. The device exhibits rail-to-rail output performance for increased dynamic range in single- or split-supply applications. The TLV2211 is fully characterized at 3 V and 5 V and is optimized for low-voltage applications.

The TLV2211, exhibiting high input impedance and low noise, is excellent for small-signal conditioning for high-impedance sources, such as piezoelectric transducers. Because of the micropower dissipation levels combined with 3-V operation, these devices work well in hand-held monitoring and remote-sensing applications. In addition, the rail-to-rail output feature with single or split supplies makes this family a great choice when interfacing with analog-to-digital converters (ADCs).



† All loads are referenced to 1.5 V.

Figure 1. Equivalent Input Noise Voltage Versus Frequency

#### AVAILABLE OPTIONS

| T <sub>A</sub> | V <sub>IOMax</sub> AT 25°C | PACKAGED DEVICES | SYMBOL | CHIP FORM‡ (Y) |
|----------------|----------------------------|------------------|--------|----------------|
|                |                            | SOT-23 (DBV)†    |        |                |
| 0°C to 70°C    | 3 mV                       | TLV2211CDBV      | VACC   | TLV2211Y       |
| -40°C to 85°C  | 3 mV                       | TLV2211IDBV      | VACI   |                |

† The DBV package available in tape and reel only.

‡ Chip forms are tested at T<sub>A</sub> = 25°C only.



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#### description (continued)

With a total area of 5.6mm<sup>2</sup>, the SOT-23 package only requires one-third the board space of the standard 8-pin SOIC package. This ultra-small package allows designers to place single amplifiers very close to the signal source, minimizing noise pick-up from long PCB traces. TI has also taken special care to provide a pinout that is optimized for board layout (see Figure 2). Both inputs are separated by GND to prevent coupling or leakage paths. The OUT and IN– terminals are on the same end of the board to provide negative feedback. Finally, gain setting resistors and decoupling capacitor are easily placed around the package.

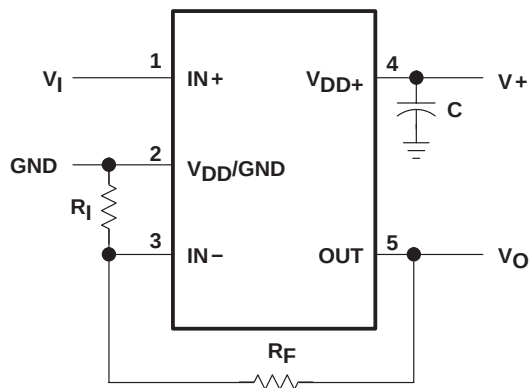
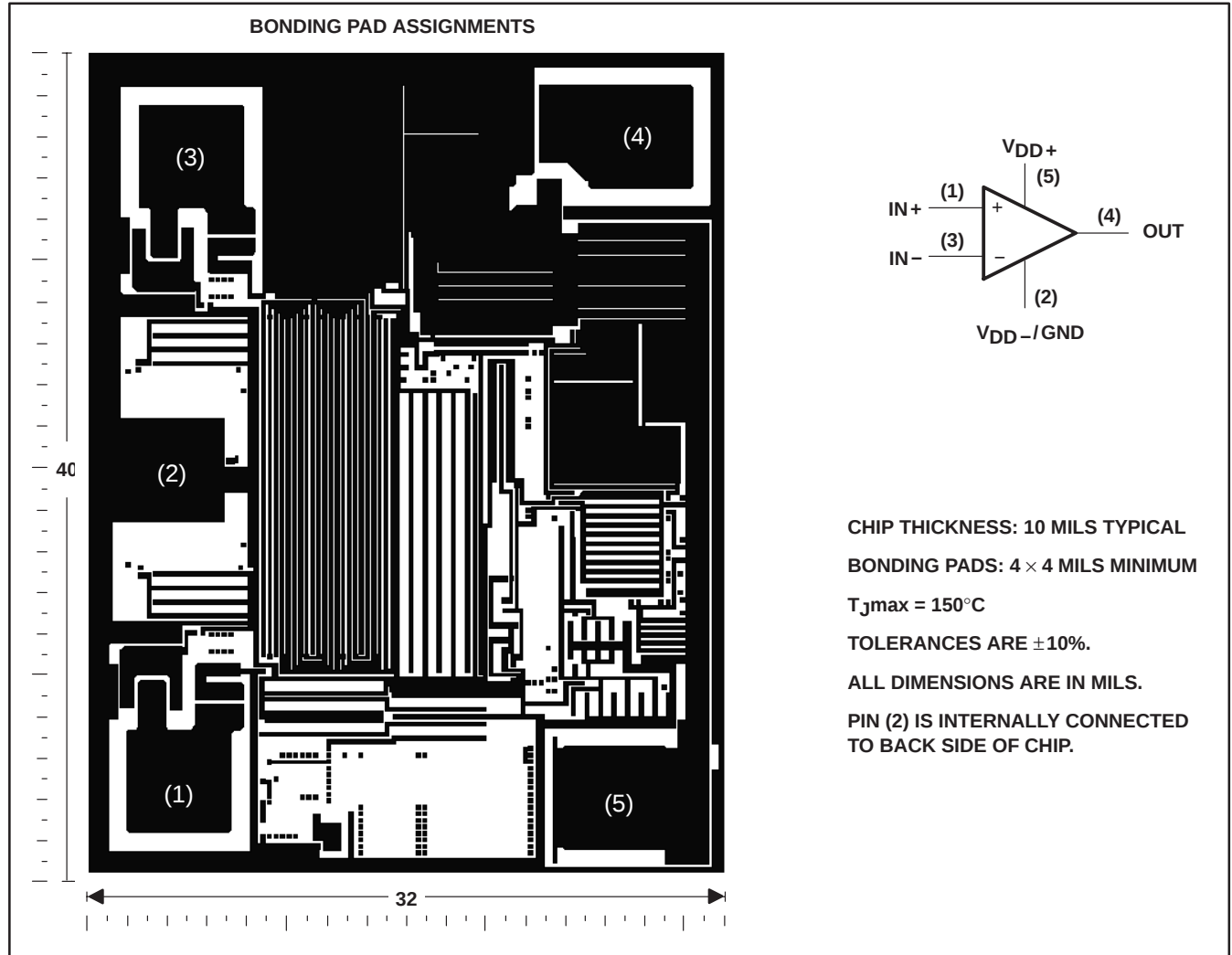


Figure 2. Typical Surface Mount Layout for a Fixed-Gain Noninverting Amplifier

### TLV2211Y chip information

This chip, when properly assembled, displays characteristics similar to the TLV2211C. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. This chip may be mounted with conductive epoxy or a gold-silicon preform.



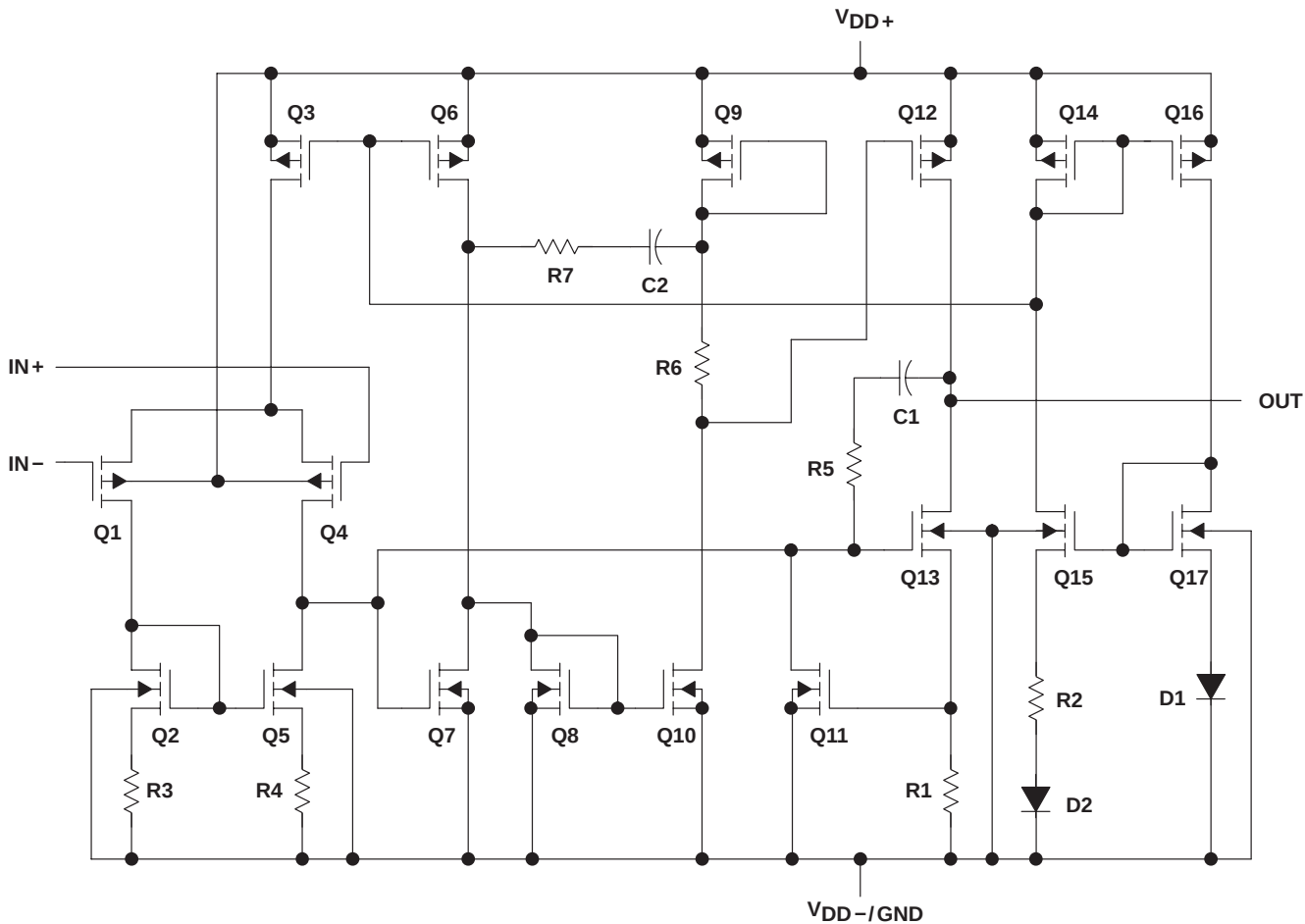
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equivalent schematic



| COMPONENT COUNT† |    |
|------------------|----|
| Transistors      | 23 |
| Diodes           | 6  |
| Resistors        | 11 |
| Capacitors       | 2  |

† Includes both amplifiers and all ESD, bias, and trim circuitry

**absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>**

|                                                                           |                              |
|---------------------------------------------------------------------------|------------------------------|
| Supply voltage, $V_{DD}$ (see Note 1)                                     | 12 V                         |
| Differential input voltage, $V_{ID}$ (see Note 2)                         | $\pm V_{DD}$                 |
| Input voltage range, $V_I$ (any input, see Note 1)                        | -0.3 V to $V_{DD}$           |
| Input current, $I_I$ (each input)                                         | $\pm 5$ mA                   |
| Output current, $I_O$                                                     | $\pm 50$ mA                  |
| Total current into $V_{DD+}$                                              | $\pm 50$ mA                  |
| Total current out of $V_{DD-}$                                            | $\pm 50$ mA                  |
| Duration of short-circuit current (at or below) 25°C (see Note 3)         | unlimited                    |
| Continuous total power dissipation                                        | See Dissipation Rating Table |
| Operating free-air temperature range, $T_A$ : TLV2211C                    | 0°C to 70°C                  |
| TLV2211I                                                                  | -40°C to 85°C                |
| Storage temperature range, $T_{stg}$                                      | -65°C to 150°C               |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: DBV package | 260°C                        |

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to  $V_{DD-}$ .  
2. Differential voltages are at the noninverting input with respect to the inverting input. Excessive current flows when input is brought below  $V_{DD-} - 0.3$  V.  
3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

**DISSIPATION RATING TABLE**

| PACKAGE | $T_A \leq 25^\circ\text{C}$<br>POWER RATING | DERATING FACTOR<br>ABOVE $T_A = 25^\circ\text{C}$ | $T_A = 70^\circ\text{C}$<br>POWER RATING | $T_A = 85^\circ\text{C}$<br>POWER RATING |
|---------|---------------------------------------------|---------------------------------------------------|------------------------------------------|------------------------------------------|
| DBV     | 150 mW                                      | 1.2 mW/°C                                         | 96 mW                                    | 78 mW                                    |

**recommended operating conditions**

|                                       | TLV2211C  |                 | TLV2211I  |                 | UNIT |
|---------------------------------------|-----------|-----------------|-----------|-----------------|------|
|                                       | MIN       | MAX             | MIN       | MAX             |      |
| Supply voltage, $V_{DD}$ (see Note 1) | 2.7       | 10              | 2.7       | 10              | V    |
| Input voltage range, $V_I$            | $V_{DD-}$ | $V_{DD+} - 1.3$ | $V_{DD-}$ | $V_{DD+} - 1.3$ | V    |
| Common-mode input voltage, $V_{IC}$   | $V_{DD-}$ | $V_{DD+} - 1.3$ | $V_{DD-}$ | $V_{DD+} - 1.3$ | V    |
| Operating free-air temperature, $T_A$ | 0         | 70              | -40       | 85              | °C   |

NOTE 1: All voltage values, except differential voltages, are with respect to  $V_{DD-}$ .

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electrical characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$  (unless otherwise noted)

| PARAMETER         |                                                                      | TEST CONDITIONS                                                                                         |                                      | T <sub>A</sub> <sup>†</sup> | TLV2211C         |     | TLV2211I          |              | UNIT  |                   |      |
|-------------------|----------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------|--------------------------------------|-----------------------------|------------------|-----|-------------------|--------------|-------|-------------------|------|
|                   |                                                                      |                                                                                                         |                                      |                             | MIN              | TYP | MAX               | MIN          |       | TYP               | MAX  |
| V <sub>IO</sub>   | Input offset voltage                                                 | V <sub>DD</sub> ± = ±1.5 V,<br>V <sub>O</sub> = 0,<br><br>V <sub>IC</sub> = 0,<br>R <sub>S</sub> = 50 Ω |                                      | Full range                  | 0.47             |     | 3                 | 0.47         |       | 3                 | mV   |
| α <sub>VIO</sub>  | Temperature coefficient of input offset voltage                      |                                                                                                         |                                      |                             | 1                |     | 1                 |              | μV/°C |                   |      |
|                   | Input offset voltage long-term drift (see Note 4)                    |                                                                                                         |                                      | 25°C                        | 0.003            |     | 0.003             |              | μV/mo |                   |      |
| I <sub>IO</sub>   | Input offset current                                                 |                                                                                                         |                                      | Full range                  | 0.5              |     | 60                | 0.5          |       | 60                | pA   |
| I <sub>IB</sub>   | Input bias current                                                   |                                                                                                         |                                      | Full range                  | 1                |     | 60                | 1            |       | 60                | pA   |
| V <sub>ICR</sub>  | Common-mode input voltage range                                      | V <sub>IO</sub>   ≤ 5 mV,<br><br>R <sub>S</sub> = 50 Ω                                                  |                                      | 25°C                        | 0<br>to<br>2     |     | −0.3<br>to<br>2.2 | 0<br>to<br>2 |       | −0.3<br>to<br>2.2 | V    |
|                   |                                                                      |                                                                                                         |                                      | Full range                  | 0<br>to<br>1.7   |     | 0<br>to<br>1.7    |              |       |                   |      |
| V <sub>OH</sub>   | High-level output voltage                                            | I <sub>OH</sub> = −100 μA                                                                               |                                      | 25°C                        | 2.94             |     | 2.94              |              | V     |                   |      |
|                   |                                                                      | I <sub>OH</sub> = −250 μA                                                                               |                                      | 25°C                        | 2.85             |     | 2.85              |              |       |                   |      |
|                   |                                                                      |                                                                                                         |                                      | Full range                  | 2.5              |     | 2.5               |              |       |                   |      |
| V <sub>OL</sub>   | Low-level output voltage                                             | V <sub>IC</sub> = 1.5 V, I <sub>OL</sub> = 50 μA                                                        |                                      | 25°C                        | 15               |     | 15                |              | mV    |                   |      |
|                   |                                                                      | V <sub>IC</sub> = 1.5 V, I <sub>OL</sub> = 500 μA                                                       |                                      | 25°C                        | 150              |     | 150               |              |       |                   |      |
|                   |                                                                      |                                                                                                         |                                      | Full range                  | 500              |     | 500               |              |       |                   |      |
| A <sub>VD</sub>   | Large-signal differential voltage amplification                      | V <sub>IC</sub> = 1.5 V,<br>V <sub>O</sub> = 1 V to 2 V                                                 | R <sub>L</sub> = 10 kΩ <sup>‡</sup>  | 25°C                        | 3                |     | 7                 | 3            |       | 7                 | V/mV |
|                   |                                                                      |                                                                                                         |                                      | Full range                  | 1                |     | 1                 |              |       |                   |      |
|                   |                                                                      |                                                                                                         | R <sub>L</sub> = 1 MΩ <sup>‡</sup>   | 25°C                        | 600              |     | 600               |              |       |                   |      |
| r <sub>i(d)</sub> | Differential input resistance                                        |                                                                                                         |                                      | 25°C                        | 10 <sup>12</sup> |     | 10 <sup>12</sup>  |              | Ω     |                   |      |
| r <sub>i(c)</sub> | Common-mode input resistance                                         |                                                                                                         |                                      | 25°C                        | 10 <sup>12</sup> |     | 10 <sup>12</sup>  |              | Ω     |                   |      |
| C <sub>i(c)</sub> | Common-mode input capacitance                                        | f = 10 kHz,                                                                                             |                                      | 25°C                        | 5                |     | 5                 |              | pF    |                   |      |
| z <sub>o</sub>    | Closed-loop output impedance                                         | f = 7 kHz,                                                                                              | A <sub>V</sub> = 1                   | 25°C                        | 200              |     | 200               |              | Ω     |                   |      |
| CMRR              | Common-mode rejection ratio                                          | V <sub>IC</sub> = 0 to 1.7 V,<br>R <sub>S</sub> = 50 Ω                                                  | V <sub>O</sub> = 1.5 V,              | 25°C                        | 65               |     | 83                | 65           |       | 83                | dB   |
|                   |                                                                      |                                                                                                         |                                      | Full range                  | 60               |     | 60                |              |       |                   |      |
| k <sub>SVR</sub>  | Supply voltage rejection ratio (ΔV <sub>DD</sub> /ΔV <sub>IO</sub> ) | V <sub>DD</sub> = 2.7 V to 8 V,<br>No load                                                              | V <sub>IC</sub> = V <sub>DD</sub> /2 | 25°C                        | 80               |     | 95                | 80           |       | 95                | dB   |
|                   |                                                                      |                                                                                                         |                                      | Full range                  | 80               |     | 80                |              |       |                   |      |
| I <sub>DD</sub>   | Supply current                                                       | V <sub>O</sub> = 1.5 V,                                                                                 | No load                              | 25°C                        | 11               |     | 25                | 11           |       | 25                | μA   |
|                   |                                                                      |                                                                                                         |                                      | Full range                  | 30               |     | 30                |              |       |                   |      |

$^\dagger$  Full range for the TLV2211C is 0°C to 70°C. Full range for the TLV2211I is –40°C to 85°C.

$^\ddagger$  Referenced to 1.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

operating characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$  (unless otherwise noted)

| PARAMETER   | TEST CONDITIONS                             | $T_A^\dagger$                                                                                        | TLV2211C   |       |       | TLV2211I |       |     | UNIT                   |
|-------------|---------------------------------------------|------------------------------------------------------------------------------------------------------|------------|-------|-------|----------|-------|-----|------------------------|
|             |                                             |                                                                                                      | MIN        | TYP   | MAX   | MIN      | TYP   | MAX |                        |
| SR          | Slew rate at unity gain                     | $V_O = 1.1\text{ V to }1.9\text{ V}, R_L = 10\text{ k}\Omega^\ddagger, C_L = 100\text{ pF}^\ddagger$ | 25°C       | 0.01  | 0.025 | 0.01     | 0.025 |     | V/ $\mu\text{s}$       |
|             |                                             |                                                                                                      | Full range | 0.005 |       | 0.005    |       |     |                        |
| $V_n$       | Equivalent input noise voltage              | $f = 10\text{ Hz}$                                                                                   | 25°C       | 80    |       | 80       |       |     | nV/ $\sqrt{\text{Hz}}$ |
|             |                                             | $f = 1\text{ kHz}$                                                                                   | 25°C       | 22    |       | 22       |       |     |                        |
| $V_{N(PP)}$ | Peak-to-peak equivalent input noise voltage | $f = 0.1\text{ Hz to }1\text{ Hz}$                                                                   | 25°C       | 660   |       | 660      |       |     | nV                     |
|             |                                             | $f = 0.1\text{ Hz to }10\text{ Hz}$                                                                  | 25°C       | 880   |       | 880      |       |     |                        |
| $I_n$       | Equivalent input noise current              |                                                                                                      | 25°C       | 0.6   |       | 0.6      |       |     | fA/ $\sqrt{\text{Hz}}$ |
|             | Gain-bandwidth product                      | $f = 10\text{ kHz}, R_L = 10\text{ k}\Omega^\ddagger, C_L = 100\text{ pF}^\ddagger$                  | 25°C       | 56    |       | 56       |       |     | kHz                    |
| $B_{OM}$    | Maximum output-swing bandwidth              | $V_{O(PP)} = 1\text{ V}, R_L = 10\text{ k}\Omega^\ddagger, A_V = 1, C_L = 100\text{ pF}^\ddagger$    | 25°C       | 7     |       | 7        |       |     | kHz                    |
| $\phi_m$    | Phase margin at unity gain                  | $R_L = 10\text{ k}\Omega^\ddagger, C_L = 100\text{ pF}^\ddagger$                                     | 25°C       | 56°   |       | 56°      |       |     |                        |
|             | Gain margin                                 |                                                                                                      | 25°C       | 20    |       | 20       |       |     | dB                     |

$^\dagger$  Full range is  $-40^\circ\text{C}$  to  $85^\circ\text{C}$ .

$^\ddagger$  Referenced to 1.5 V

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electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)

| PARAMETER         |                                                                      | TEST CONDITIONS                                                                                        |                                     | T <sub>A</sub> <sup>†</sup> | TLV2211C         |                   |                  | TLV2211I     |                   |     | UNIT |
|-------------------|----------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------|-------------------------------------|-----------------------------|------------------|-------------------|------------------|--------------|-------------------|-----|------|
|                   |                                                                      |                                                                                                        |                                     |                             | MIN              | TYP               | MAX              | MIN          | TYP               | MAX |      |
| V <sub>IO</sub>   | Input offset voltage                                                 | V <sub>DD±</sub> = ±2.5 V,<br>V <sub>O</sub> = 0,<br><br>V <sub>IC</sub> = 0,<br>R <sub>S</sub> = 50 Ω |                                     | Full range                  | 0.45             |                   | 3                | 0.45         |                   | 3   | mV   |
| α <sub>VIO</sub>  | Temperature coefficient of input offset voltage                      |                                                                                                        |                                     |                             | 0.5              |                   | 0.5              |              | μV/°C             |     |      |
|                   | Input offset voltage long-term drift (see Note 5)                    |                                                                                                        |                                     | 25°C                        | 0.003            |                   | 0.003            |              | μV/mo             |     |      |
| I <sub>IO</sub>   | Input offset current                                                 |                                                                                                        |                                     | 25°C                        | 0.5              |                   | 60               |              | pA                |     |      |
|                   |                                                                      |                                                                                                        |                                     | Full range                  | 150              |                   | 150              |              |                   |     |      |
| I <sub>IB</sub>   | Input bias current                                                   |                                                                                                        |                                     | 25°C                        | 1                |                   | 60               |              | pA                |     |      |
|                   |                                                                      | Full range                                                                                             | 150                                 |                             | 150              |                   |                  |              |                   |     |      |
| V <sub>ICR</sub>  | Common-mode input voltage range                                      | V <sub>IO</sub>   ≤5 mV<br><br>R <sub>S</sub> = 50 Ω                                                   |                                     | 25°C                        | 0<br>to<br>4     | −0.3<br>to<br>4.2 |                  | 0<br>to<br>4 | −0.3<br>to<br>4.2 | V   |      |
|                   |                                                                      |                                                                                                        |                                     | Full range                  | 0<br>to<br>3.5   |                   | 0<br>to<br>3.5   |              |                   |     |      |
| V <sub>OH</sub>   | High-level output voltage                                            | I <sub>OH</sub> = −100 μA                                                                              |                                     | 25°C                        | 4.95             |                   | 4.95             |              | V                 |     |      |
|                   |                                                                      | I <sub>OH</sub> = −250 μA                                                                              |                                     | 25°C                        | 4.875            |                   | 4.875            |              |                   |     |      |
|                   |                                                                      |                                                                                                        |                                     | Full range                  | 4.5              |                   | 4.5              |              |                   |     |      |
| V <sub>OL</sub>   | Low-level output voltage                                             | V <sub>IC</sub> = 2.5 V, I <sub>OL</sub> = 50 μA                                                       |                                     | 25°C                        | 12               |                   | 12               |              | mV                |     |      |
|                   |                                                                      | V <sub>IC</sub> = 2.5 V, I <sub>OL</sub> = 500 μA                                                      |                                     | 25°C                        | 120              |                   | 120              |              |                   |     |      |
|                   |                                                                      |                                                                                                        |                                     | Full range                  | 500              |                   | 500              |              |                   |     |      |
| A <sub>VD</sub>   | Large-signal differential voltage amplification                      | V <sub>IC</sub> = 2.5 V,<br>V <sub>O</sub> = 1 V to 4 V                                                | R <sub>L</sub> = 10 kΩ <sup>‡</sup> | 25°C                        | 6                | 12                | 6                | 12           | V/mV              |     |      |
|                   |                                                                      |                                                                                                        |                                     | Full range                  | 3                |                   | 3                |              |                   |     |      |
|                   |                                                                      |                                                                                                        | R <sub>L</sub> = 1 MΩ <sup>‡</sup>  | 25°C                        | 800              |                   | 800              |              |                   |     |      |
| r <sub>i(d)</sub> | Differential input resistance                                        |                                                                                                        |                                     | 25°C                        | 10 <sup>12</sup> |                   | 10 <sup>12</sup> |              | Ω                 |     |      |
| r <sub>i(c)</sub> | Common-mode input resistance                                         |                                                                                                        |                                     | 25°C                        | 10 <sup>12</sup> |                   | 10 <sup>12</sup> |              | Ω                 |     |      |
| c <sub>i(c)</sub> | Common-mode input capacitance                                        | f = 10 kHz,                                                                                            |                                     | 25°C                        | 5                |                   | 5                |              | pF                |     |      |
| z <sub>o</sub>    | Closed-loop output impedance                                         | f = 7 kHz, A <sub>V</sub> = 1                                                                          |                                     | 25°C                        | 200              |                   | 200              |              | Ω                 |     |      |
| CMRR              | Common-mode rejection ratio                                          | V <sub>IC</sub> = 0 to 2.7 V,<br>R <sub>S</sub> = 50 Ω, V <sub>O</sub> = 2.5 V                         |                                     | 25°C                        | 70               | 83                | 70               | 83           | dB                |     |      |
|                   |                                                                      |                                                                                                        |                                     | Full range                  | 70               |                   | 70               |              |                   |     |      |
| k <sub>SVR</sub>  | Supply voltage rejection ratio (ΔV <sub>DD</sub> /ΔV <sub>IO</sub> ) | V <sub>DD</sub> = 4.4 V to 8 V, No load, V <sub>IC</sub> = V <sub>DD</sub> /2,                         |                                     | 25°C                        | 80               | 95                | 80               | 95           | dB                |     |      |
|                   |                                                                      |                                                                                                        |                                     | Full range                  | 80               |                   | 80               |              |                   |     |      |
| I <sub>DD</sub>   | Supply current                                                       | V <sub>O</sub> = 2.5 V, No load                                                                        |                                     | 25°C                        | 13               | 25                | 13               | 25           | μA                |     |      |
|                   |                                                                      |                                                                                                        |                                     | Full range                  | 30               |                   | 30               |              |                   |     |      |

† Full range for the TLV2211C is 0°C to 70°C. Full range for the TLV2211I is –40°C to 85°C.

‡ Referenced to 1.5 V

NOTE 5: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)

| PARAMETER                                               | TEST CONDITIONS                                                                                      | $T_A^\dagger$ | TLV2211C |       |     | TLV2211I |       |     | UNIT                   |
|---------------------------------------------------------|------------------------------------------------------------------------------------------------------|---------------|----------|-------|-----|----------|-------|-----|------------------------|
|                                                         |                                                                                                      |               | MIN      | TYP   | MAX | MIN      | TYP   | MAX |                        |
| SR Slew rate at unity gain                              | $V_O = 1.5\text{ V to }3.5\text{ V}, R_L = 10\text{ k}\Omega^\ddagger, C_L = 100\text{ pF}^\ddagger$ | 25°C          | 0.01     | 0.025 |     | 0.01     | 0.025 |     | V/ $\mu\text{s}$       |
|                                                         |                                                                                                      | Full range    | 0.005    |       |     | 0.005    |       |     |                        |
| $V_n$ Equivalent input noise voltage                    | $f = 10\text{ Hz}$                                                                                   | 25°C          |          | 72    |     |          | 72    |     | nV/ $\sqrt{\text{Hz}}$ |
|                                                         | $f = 1\text{ kHz}$                                                                                   | 25°C          |          | 21    |     |          | 21    |     |                        |
| $V_{N(PP)}$ Peak-to-peak equivalent input noise voltage | $f = 0.1\text{ Hz to }1\text{ Hz}$                                                                   | 25°C          |          | 600   |     |          | 600   |     | nV                     |
|                                                         | $f = 0.1\text{ Hz to }10\text{ Hz}$                                                                  | 25°C          |          | 800   |     |          | 800   |     |                        |
| $I_n$ Equivalent input noise current                    |                                                                                                      | 25°C          |          | 0.6   |     |          | 0.6   |     | fA/ $\sqrt{\text{Hz}}$ |
| Gain-bandwidth product                                  | $f = 10\text{ kHz}, R_L = 10\text{ k}\Omega^\ddagger, C_L = 100\text{ pF}^\ddagger$                  | 25°C          |          | 65    |     |          | 65    |     | kHz                    |
| $B_{OM}$ Maximum output-swing bandwidth                 | $V_{O(PP)} = 2\text{ V}, R_L = 10\text{ k}\Omega^\ddagger, A_V = 1, C_L = 100\text{ pF}^\ddagger$    | 25°C          |          | 7     |     |          | 7     |     | kHz                    |
| $\phi_m$ Phase margin at unity gain                     | $R_L = 10\text{ k}\Omega^\ddagger, C_L = 100\text{ pF}^\ddagger$                                     | 25°C          |          | 56°   |     |          | 56°   |     |                        |
| Gain margin                                             |                                                                                                      | 25°C          |          | 22    |     |          | 22    |     | dB                     |

$^\dagger$  Full range is  $-40^\circ\text{C}$  to  $85^\circ\text{C}$ .

$^\ddagger$  Referenced to 1.5 V

electrical characteristics at  $V_{DD} = 3\text{ V}, T_A = 25^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                                                                  | TEST CONDITIONS                                                                 | TLV2211Y                          |             |     | UNIT          |
|----------------------------------------------------------------------------|---------------------------------------------------------------------------------|-----------------------------------|-------------|-----|---------------|
|                                                                            |                                                                                 | MIN                               | TYP         | MAX |               |
| $V_{IO}$ Input offset voltage                                              | $V_{DD\pm} = \pm 1.5\text{ V}, V_O = 0, V_{IC} = 0, R_S = 50\text{ }\Omega$     |                                   | 0.47        |     | mV            |
| $I_{IO}$ Input offset current                                              |                                                                                 |                                   | 0.5         | 60  | pA            |
| $I_{IB}$ Input bias current                                                |                                                                                 |                                   | 1           | 60  | pA            |
| $V_{ICR}$ Common-mode input voltage range                                  | $ V_{IO}  \leq 5\text{ mV}, R_S = 50\text{ }\Omega$                             |                                   | -0.3 to 2.2 |     | V             |
| $V_{OH}$ High-level output voltage                                         | $I_{OH} = -100\text{ }\mu\text{A}$                                              |                                   | 2.94        |     | V             |
|                                                                            | $I_{OH} = -200\text{ }\mu\text{A}$                                              |                                   | 2.85        |     |               |
| $V_{OL}$ Low-level output voltage                                          | $V_{IC} = 0, I_{OL} = 50\text{ }\mu\text{A}$                                    |                                   | 15          |     | mV            |
|                                                                            | $V_{IC} = 0, I_{OL} = 500\text{ }\mu\text{A}$                                   |                                   | 150         |     |               |
| $A_{VD}$ Large-signal differential voltage amplification                   | $V_{IC} = 1.5\text{ V}, V_O = 1\text{ V to }2\text{ V}$                         | $R_L = 10\text{ k}\Omega^\dagger$ | 7           |     | V/mV          |
|                                                                            |                                                                                 | $R_L = 1\text{ M}\Omega^\dagger$  | 600         |     |               |
| $r_{i(d)}$ Differential input resistance                                   |                                                                                 |                                   | $10^{12}$   |     | $\Omega$      |
| $r_{i(c)}$ Common-mode input resistance                                    |                                                                                 |                                   | $10^{12}$   |     | $\Omega$      |
| $c_{i(c)}$ Common-mode input capacitance                                   | $f = 10\text{ kHz}$                                                             |                                   | 5           |     | pF            |
| $z_o$ Closed-loop output impedance                                         | $f = 7\text{ kHz}, A_V = 1$                                                     |                                   | 200         |     | $\Omega$      |
| CMRR Common-mode rejection ratio                                           | $V_{IC} = 0\text{ to }1.7\text{ V}, V_O = 1.5\text{ V}, R_S = 50\text{ }\Omega$ |                                   | 83          |     | dB            |
| $k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ ) | $V_{DD} = 2.7\text{ V to }8\text{ V}, V_{IC} = V_{DD}/2, \text{ No load}$       |                                   | 95          |     | dB            |
| $I_{DD}$ Supply current                                                    | $V_O = 1.5\text{ V}, \text{ No load}$                                           |                                   | 11          |     | $\mu\text{A}$ |

$^\dagger$  Referenced to 1.5 V

# TLV2211, TLV2211Y

## Advanced LinCMOS™ RAIL-TO-RAIL

### MICROPOWER SINGLE OPERATIONAL AMPLIFIERS

SLOS156E – MAY 1996 – REVISED SEPTEMBER 2006

electrical characteristics at  $V_{DD} = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                                                                  | TEST CONDITIONS                                                                  | TLV2211Y                          |                |     | UNIT          |
|----------------------------------------------------------------------------|----------------------------------------------------------------------------------|-----------------------------------|----------------|-----|---------------|
|                                                                            |                                                                                  | MIN                               | TYP            | MAX |               |
| $V_{IO}$ Input offset voltage                                              | $V_{DD} \pm \pm 2.5\text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ ,<br>$R_S = 50\ \Omega$ |                                   | 0.45           |     | mV            |
| $I_{IO}$ Input offset current                                              |                                                                                  |                                   | 0.5            | 60  | pA            |
| $I_{IB}$ Input bias current                                                |                                                                                  |                                   | 1              | 60  | pA            |
| $V_{ICR}$ Common-mode input voltage range                                  | $ V_{IO}  \leq 5\text{ mV}$ , $R_S = 50\ \Omega$                                 |                                   | –0.3<br>to 4.2 |     | V             |
| $V_{OH}$ High-level output voltage                                         | $I_{OH} = -100\ \mu\text{A}$                                                     |                                   | 4.95           |     | V             |
|                                                                            | $I_{OH} = -250\ \mu\text{A}$                                                     |                                   | 4.875          |     |               |
| $V_{OL}$ Low-level output voltage                                          | $V_{IC} = 2.5\text{ V}$ , $I_{OL} = 50\ \mu\text{A}$                             |                                   | 12             |     | mV            |
|                                                                            | $V_{IC} = 2.5\text{ V}$ , $I_{OL} = 500\ \mu\text{A}$                            |                                   | 120            |     |               |
| $A_{VD}$ Large-signal differential voltage amplification                   | $V_{IC} = 2.5\text{ V}$ , $V_O = 1\text{ V to }4\text{ V}$                       | $R_L = 10\text{ k}\Omega^\dagger$ | 12             |     | V/mV          |
|                                                                            |                                                                                  | $R_L = 1\text{ M}\Omega^\dagger$  | 800            |     |               |
| $r_{i(d)}$ Differential input resistance                                   |                                                                                  |                                   | $10^{12}$      |     | $\Omega$      |
| $r_{i(c)}$ Common-mode input resistance                                    |                                                                                  |                                   | $10^{12}$      |     | $\Omega$      |
| $c_{i(c)}$ Common-mode input capacitance                                   | $f = 10\text{ kHz}$                                                              |                                   | 5              |     | pF            |
| $z_o$ Closed-loop output impedance                                         | $f = 7\text{ kHz}$ , $A_V = 1$                                                   |                                   | 200            |     | $\Omega$      |
| CMRR Common-mode rejection ratio                                           | $V_{IC} = 0\text{ to }2.7\text{ V}$ , $V_O = 2.5\text{ V}$ , $R_S = 50\ \Omega$  |                                   | 83             |     | dB            |
| $k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ ) | $V_{DD} = 4.4\text{ V to }8\text{ V}$ , $V_{IC} = V_{DD}/2$ , No load            |                                   | 95             |     | dB            |
| $I_{DD}$ Supply current                                                    | $V_O = 2.5\text{ V}$ , No load                                                   |                                   | 13             |     | $\mu\text{A}$ |

$^\dagger$  Referenced to 1.5 V

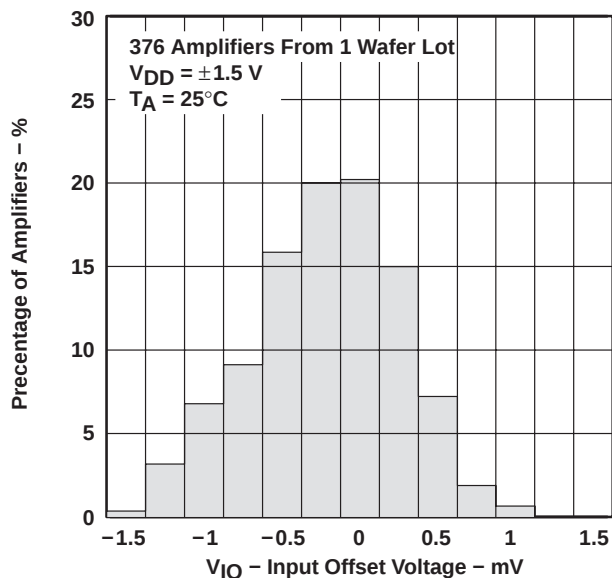
## TYPICAL CHARACTERISTICS

**Table of Graphs**

|                 |                                              |                                                               | FIGURE                 |
|-----------------|----------------------------------------------|---------------------------------------------------------------|------------------------|
| $V_{IO}$        | Input offset voltage                         | Distribution<br>vs Common-mode input voltage                  | 3, 4<br>5, 6           |
| $\alpha_{VIO}$  | Input offset voltage temperature coefficient | Distribution                                                  | 7, 8                   |
| $I_{IB}/I_{IO}$ | Input bias and input offset currents         | vs Free-air temperature                                       | 9                      |
| $V_I$           | Input voltage                                | vs Supply voltage<br>vs Free-air temperature                  | 10<br>11               |
| $V_{OH}$        | High-level output voltage                    | vs High-level output current                                  | 12, 15                 |
| $V_{OL}$        | Low-level output voltage                     | vs Low-level output current                                   | 13, 14, 16             |
| $V_{O(PP)}$     | Maximum peak-to-peak output voltage          | vs Frequency                                                  | 17                     |
| $I_{OS}$        | Short-circuit output current                 | vs Supply voltage<br>vs Free-air temperature                  | 18<br>19               |
| $V_O$           | Output voltage                               | vs Differential input voltage                                 | 20, 21                 |
| $A_{VD}$        | Differential voltage amplification           | vs Load resistance<br>vs Frequency<br>vs Free-air temperature | 22<br>23, 24<br>25, 26 |
| $z_o$           | Output impedance                             | vs Frequency                                                  | 27, 28                 |
| CMRR            | Common-mode rejection ratio                  | vs Frequency<br>vs Free-air temperature                       | 29<br>30               |
| $k_{SVR}$       | Supply-voltage rejection ratio               | vs Frequency<br>vs Free-air temperature                       | 31, 32<br>33           |
| $I_{DD}$        | Supply current                               | vs Supply voltage                                             | 34                     |
| SR              | Slew rate                                    | vs Load capacitance<br>vs Free-air temperature                | 35<br>36               |
| $V_O$           | Large-signal pulse response                  | vs Time                                                       | 37, 38, 39, 40         |
| $V_O$           | Small-signal pulse response                  | vs Time                                                       | 41, 42, 43, 44         |
| $V_n$           | Equivalent input noise voltage               | vs Frequency                                                  | 45, 46                 |
|                 | Noise voltage (referred to input)            | Over a 10-second period                                       | 47                     |
| THD + N         | Total harmonic distortion plus noise         | vs Frequency                                                  | 48                     |
|                 | Gain-bandwidth product                       | vs Free-air temperature<br>vs Supply voltage                  | 49<br>50               |
| $\phi_m$        | Phase margin                                 | vs Frequency<br>vs Load capacitance                           | 23, 24<br>51           |
|                 | Gain margin                                  | vs Load capacitance                                           | 52                     |
| $B_1$           | Unity-gain bandwidth                         | vs Load capacitance                                           | 53                     |

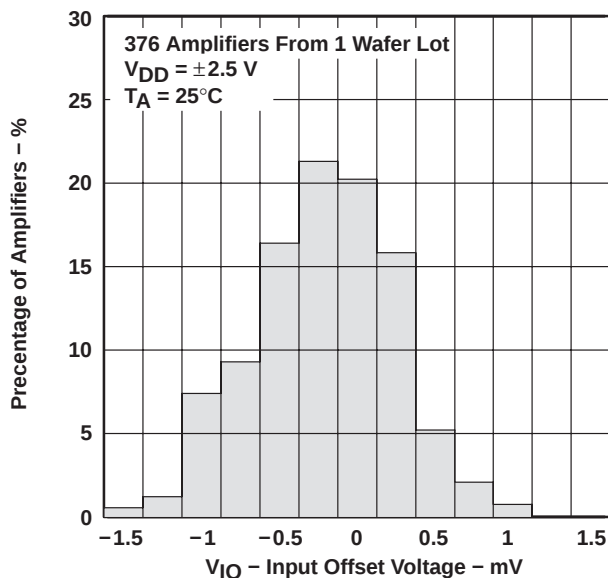
## TYPICAL CHARACTERISTICS

**DISTRIBUTION OF TLV2211  
INPUT OFFSET VOLTAGE**



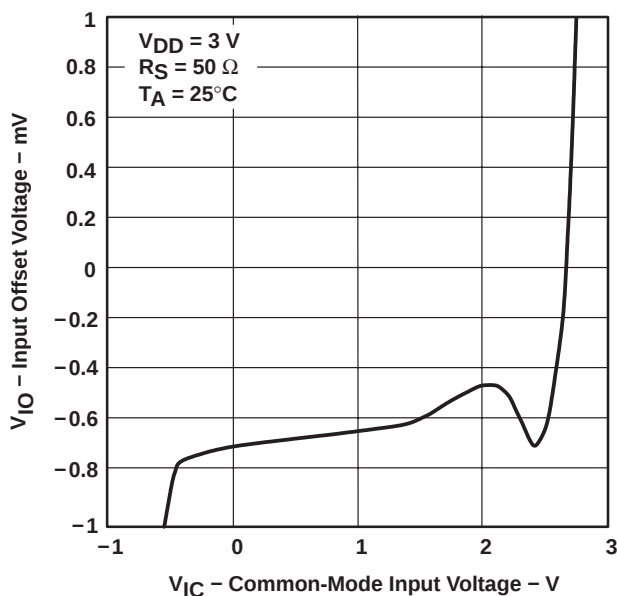
**Figure 3**

**DISTRIBUTION OF TLV2211  
INPUT OFFSET VOLTAGE**



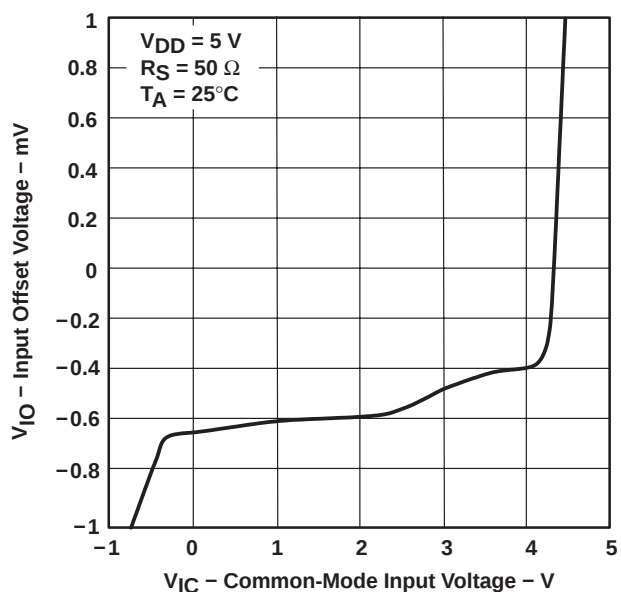
**Figure 4**

**INPUT OFFSET VOLTAGE†  
vs  
COMMON-MODE INPUT VOLTAGE**



**Figure 5**

**INPUT OFFSET VOLTAGE†  
vs  
COMMON-MODE INPUT VOLTAGE**



**Figure 6**

† For all curves where  $V_{DD} = 5 \text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3 \text{ V}$ , all loads are referenced to 1.5 V.

## TYPICAL CHARACTERISTICS

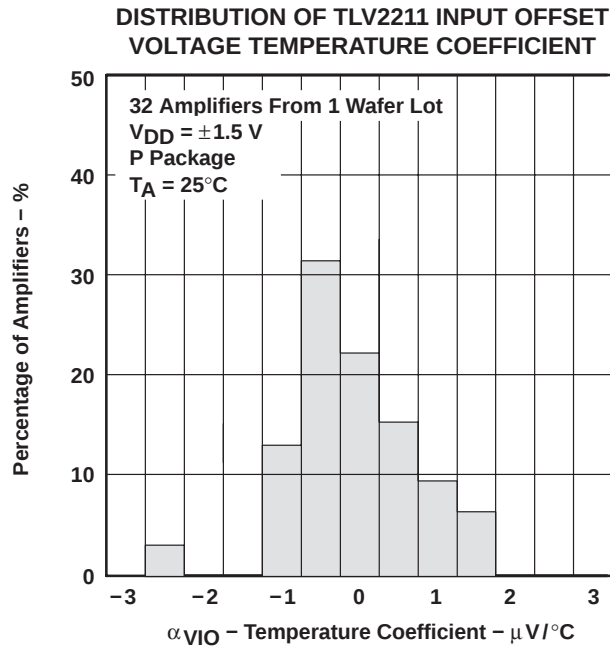


Figure 7

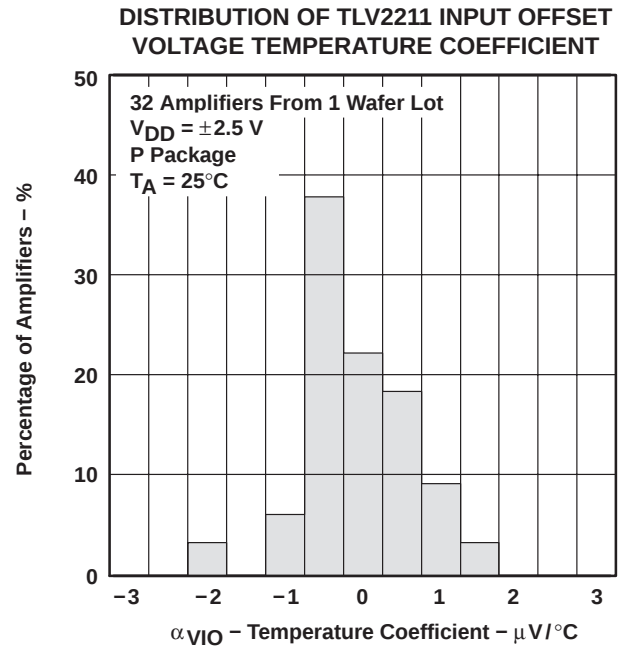


Figure 8

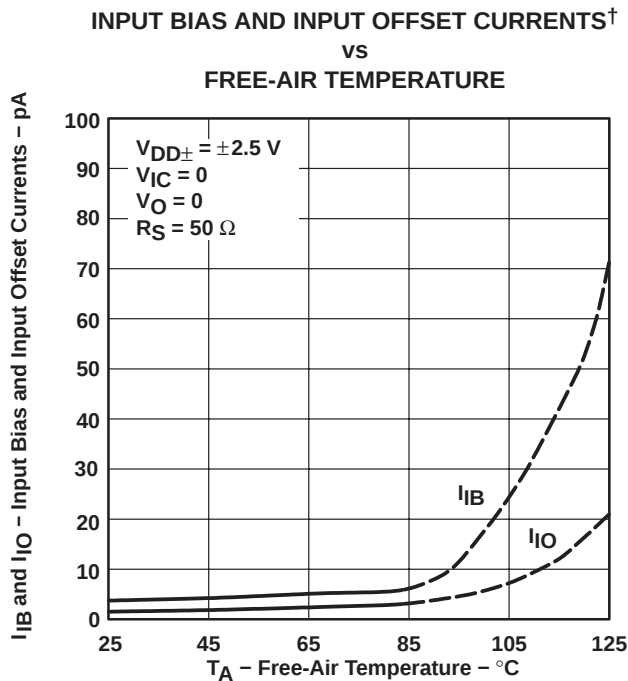


Figure 9

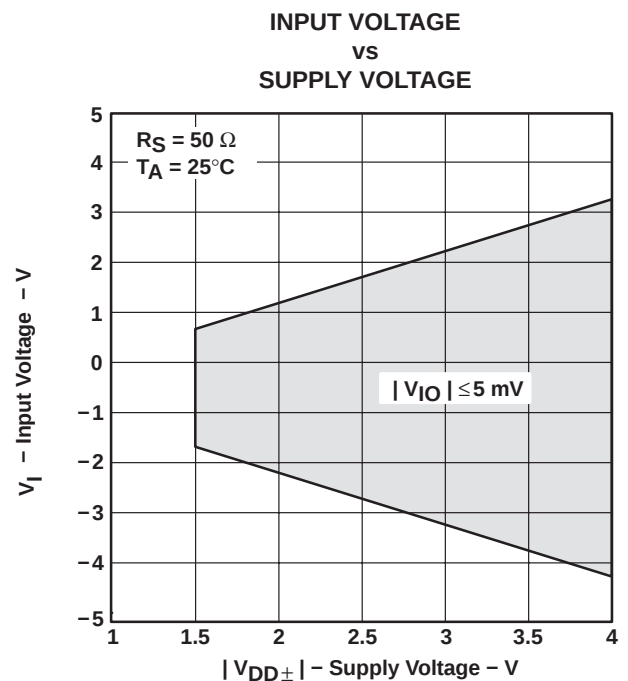


Figure 10

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

## TYPICAL CHARACTERISTICS

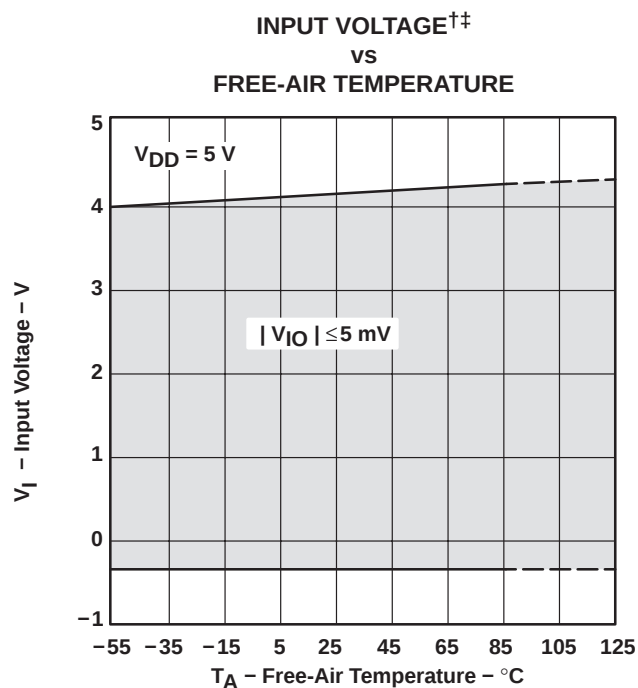


Figure 11

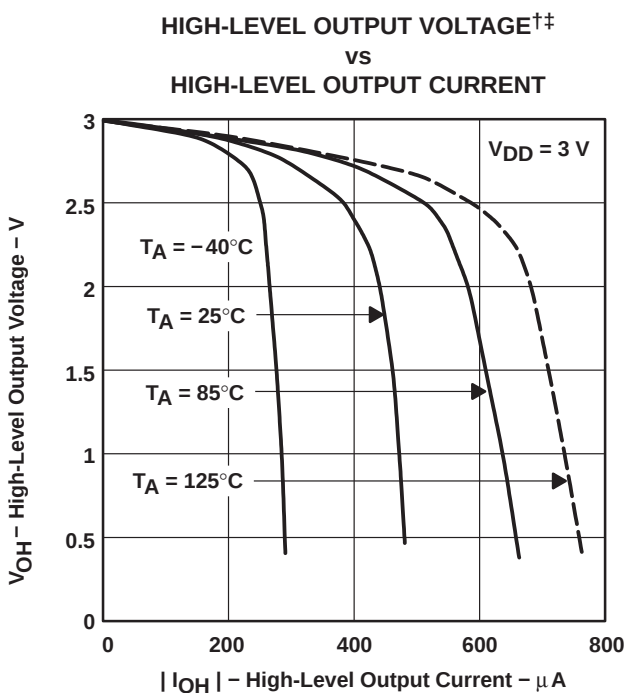


Figure 12

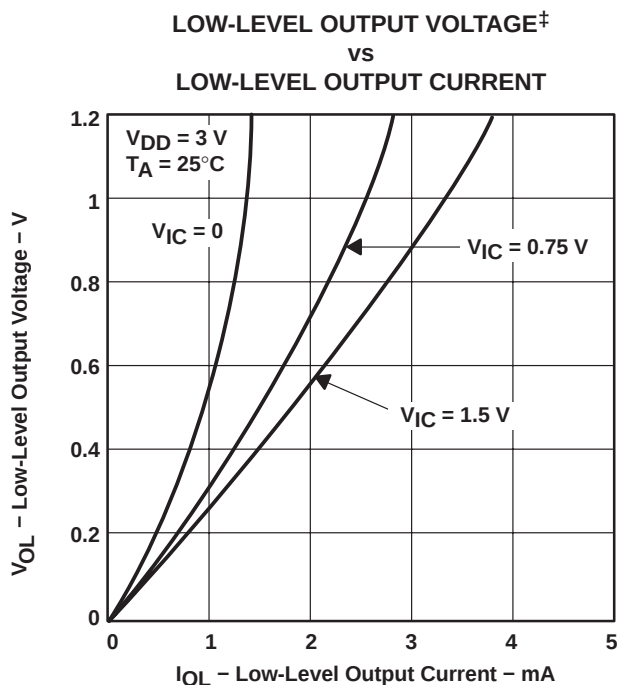


Figure 13

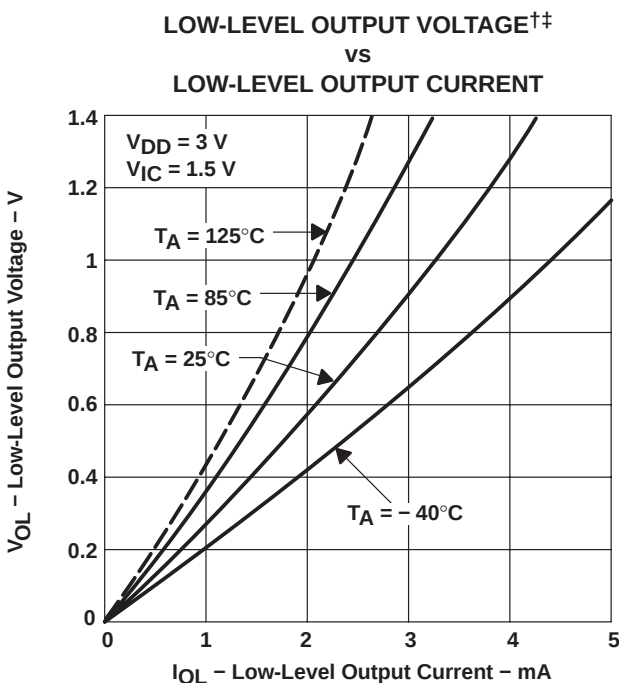
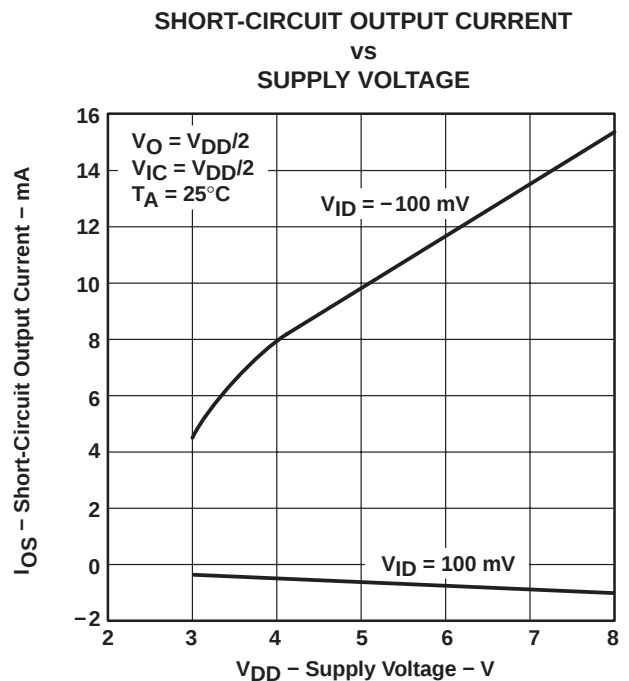
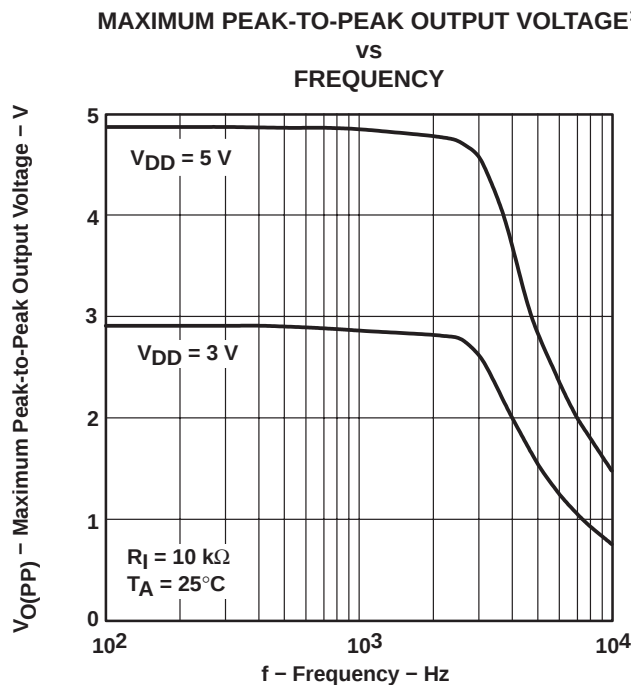
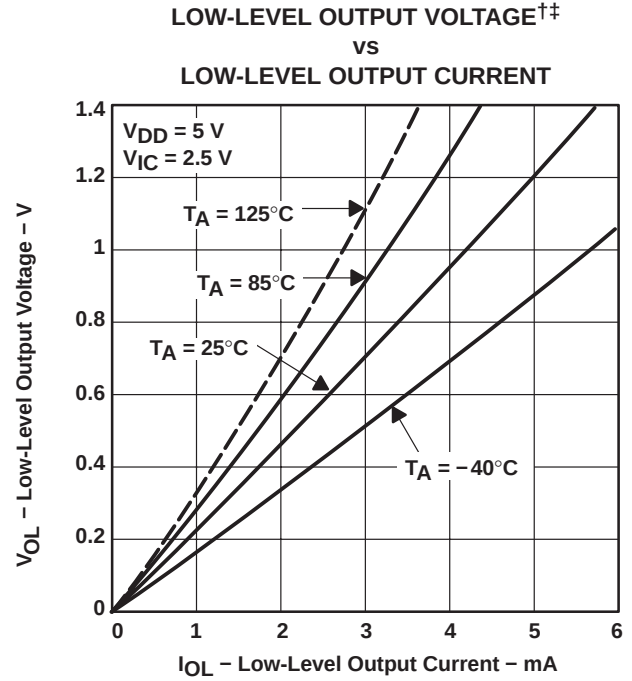
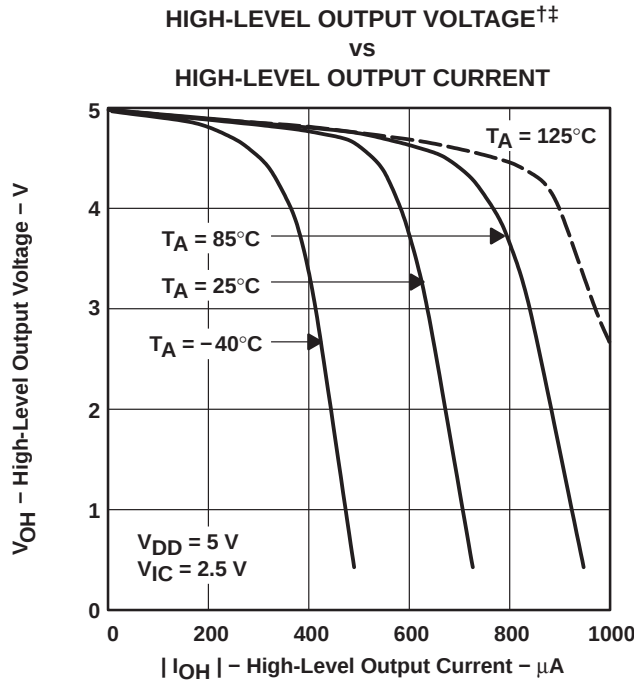


Figure 14

<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

<sup>‡</sup> For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

## TYPICAL CHARACTERISTICS



<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

<sup>‡</sup> For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

# TLV2211, TLV2211Y

## Advanced LinCMOS™ RAIL-TO-RAIL

### MICROPOWER SINGLE OPERATIONAL AMPLIFIERS

SLOS156E – MAY 1996 – REVISED SEPTEMBER 2006

#### TYPICAL CHARACTERISTICS

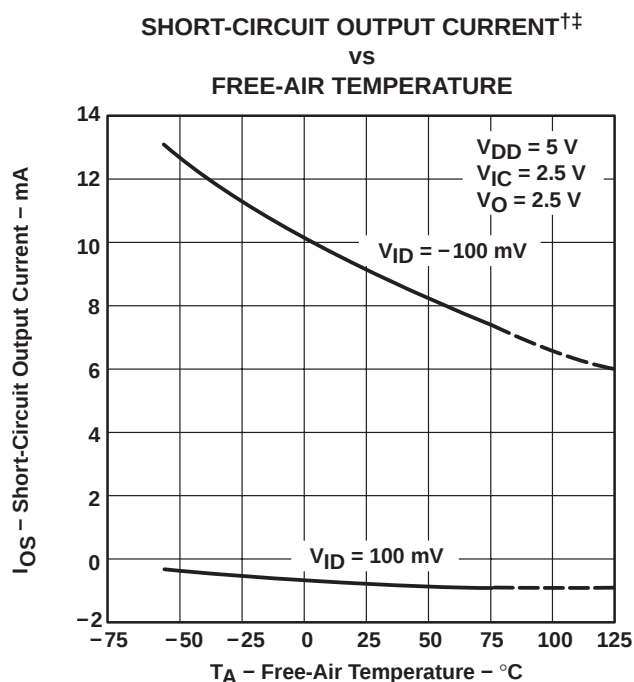


Figure 19

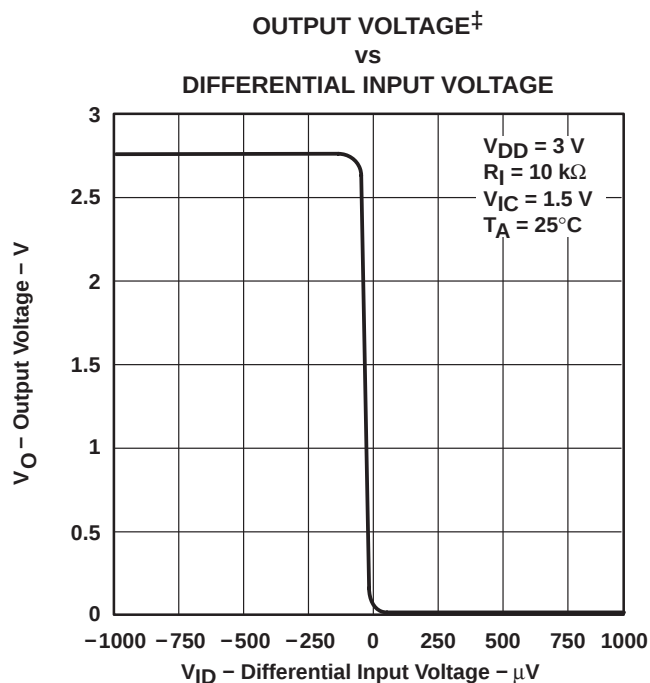


Figure 20

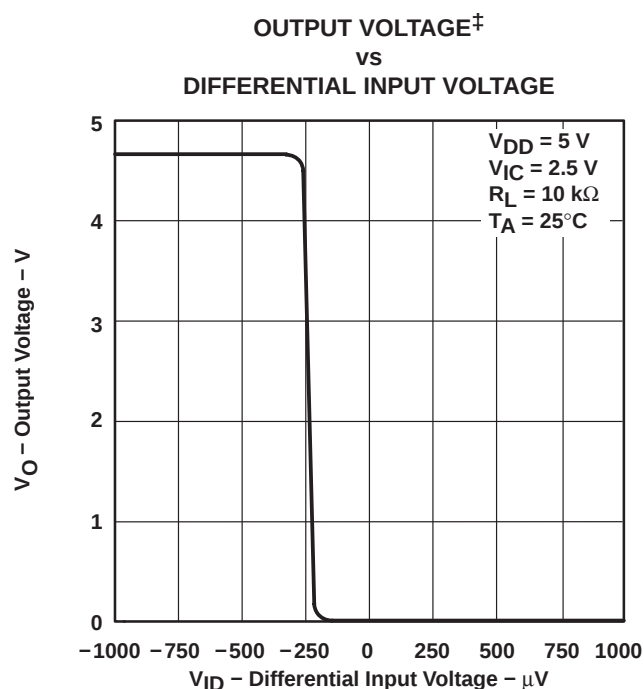


Figure 21

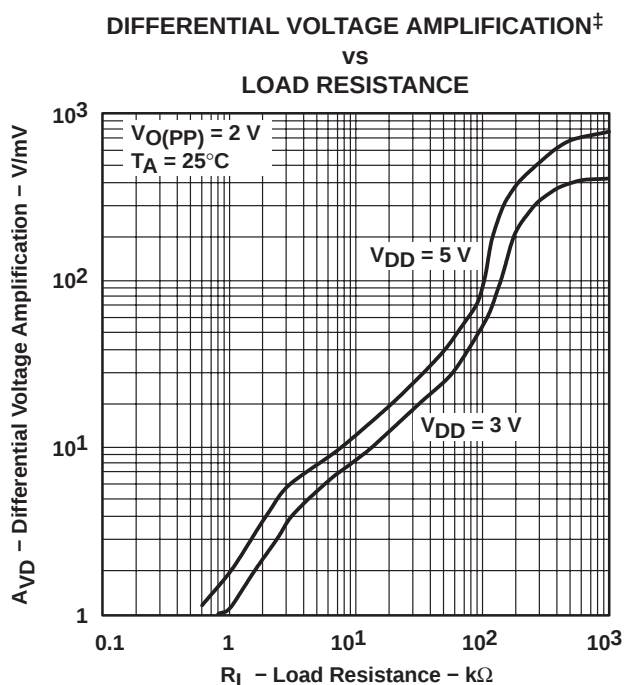


Figure 22

<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

<sup>‡</sup> For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

## TYPICAL CHARACTERISTICS

### LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN†

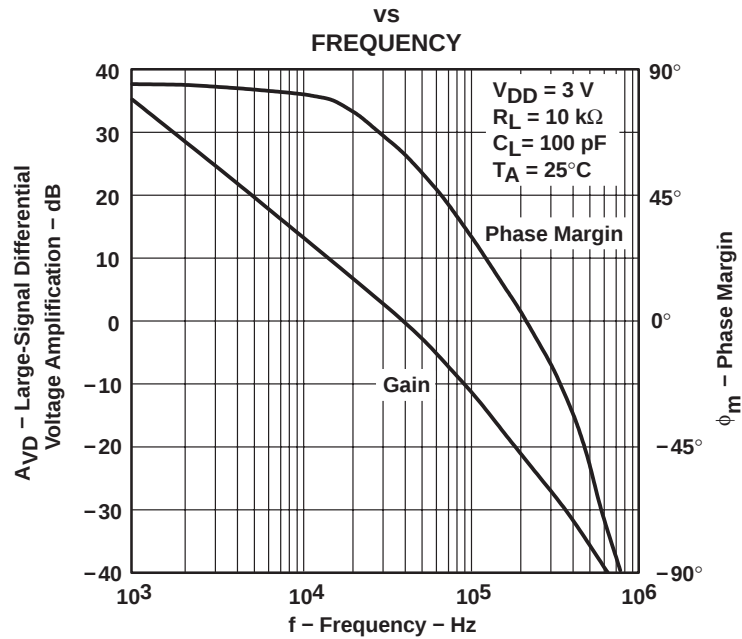


Figure 23

### LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN†

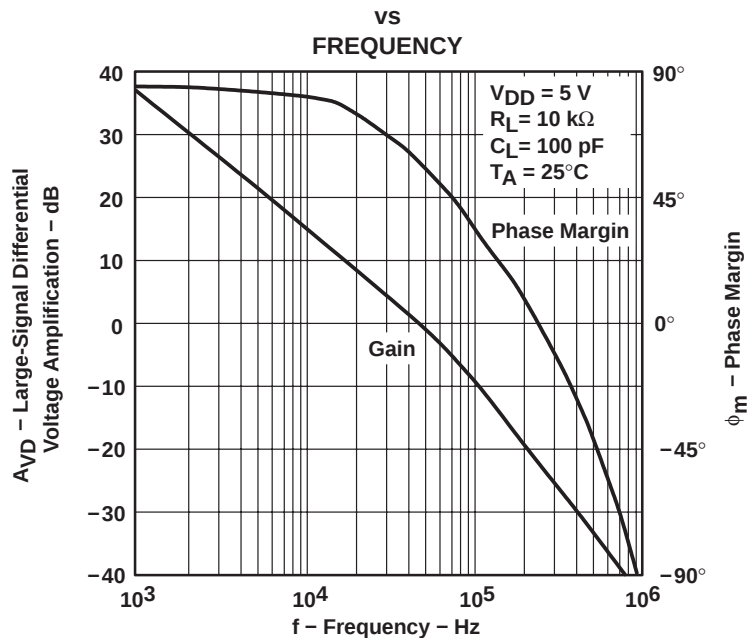
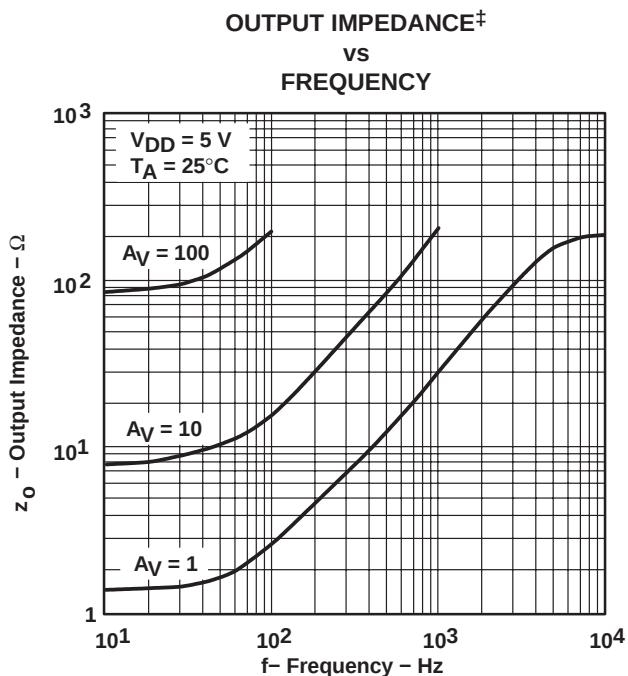
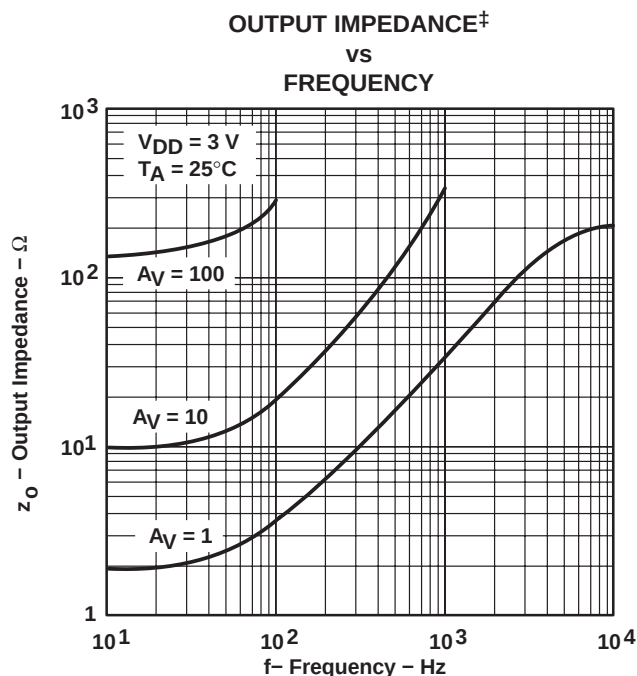
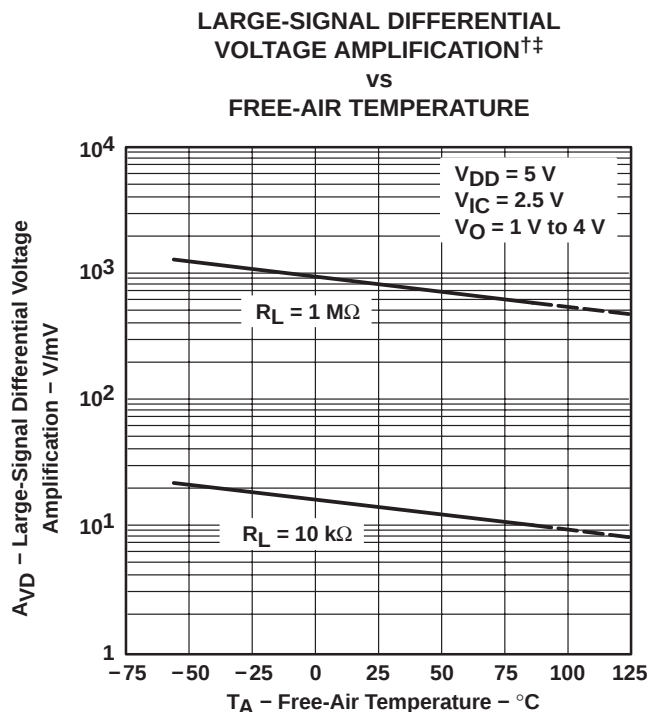
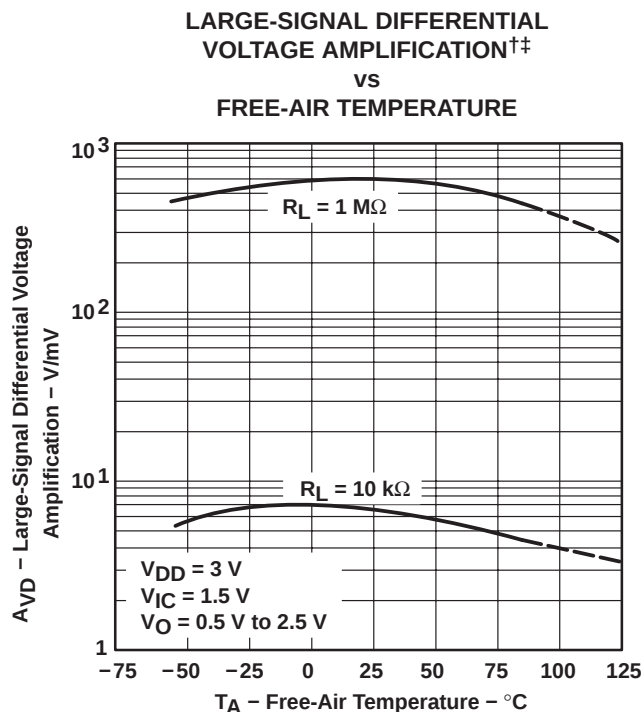


Figure 24

† For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

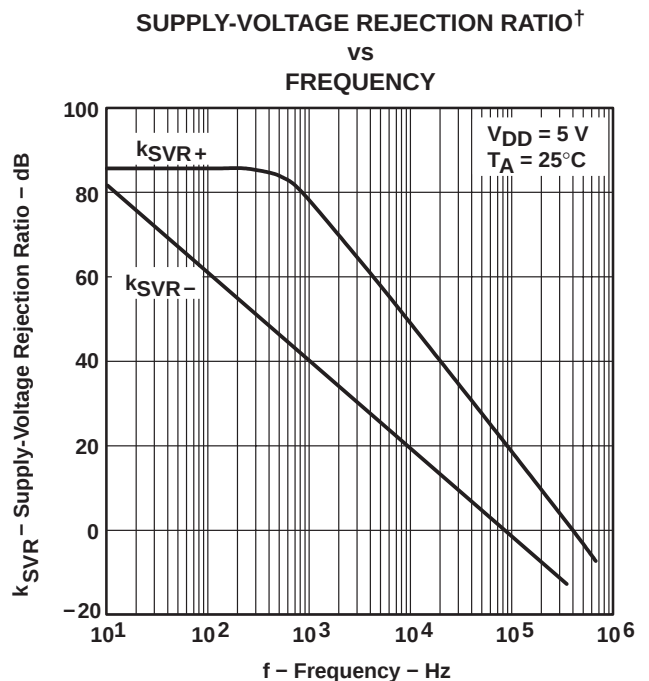
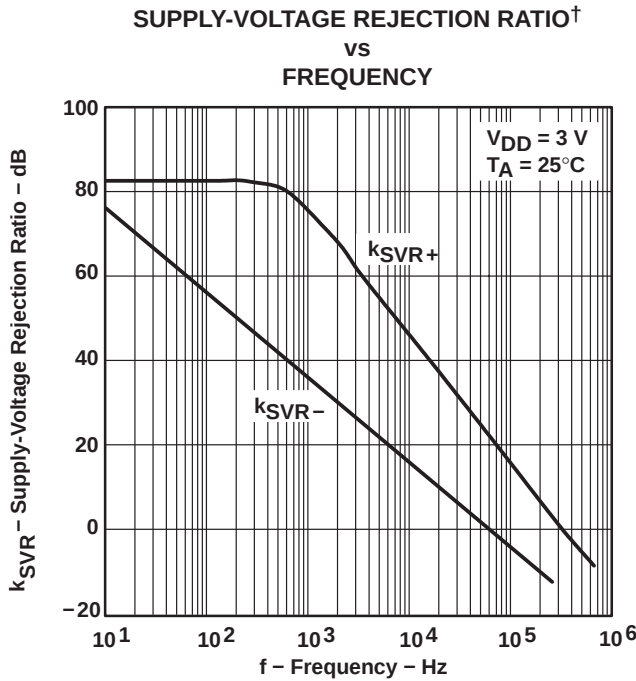
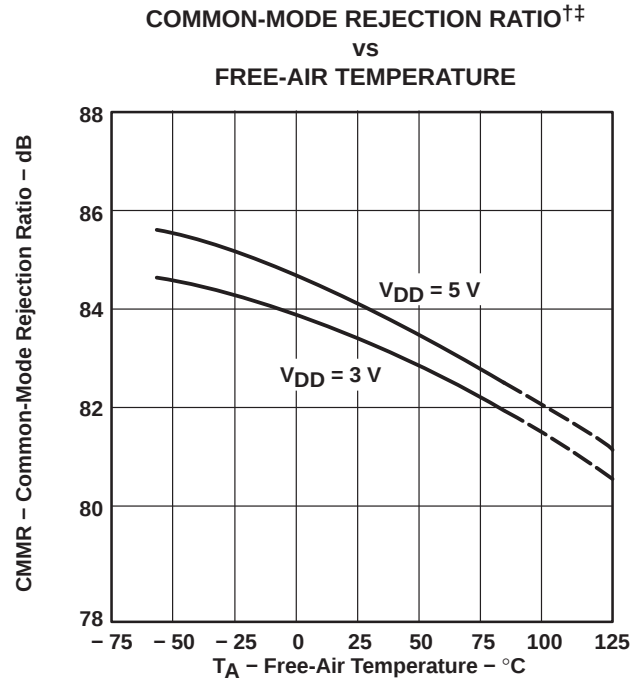
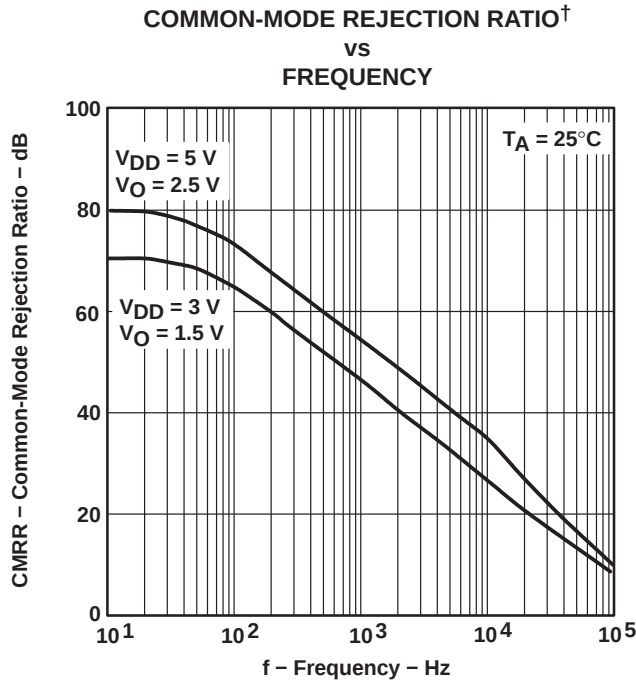
## TYPICAL CHARACTERISTICS



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

## TYPICAL CHARACTERISTICS



<sup>†</sup> For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

<sup>‡</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

# TLV2211, TLV2211Y

## Advanced LinCMOS™ RAIL-TO-RAIL

### MICROPOWER SINGLE OPERATIONAL AMPLIFIERS

SLOS156E – MAY 1996 – REVISED SEPTEMBER 2006

#### TYPICAL CHARACTERISTICS

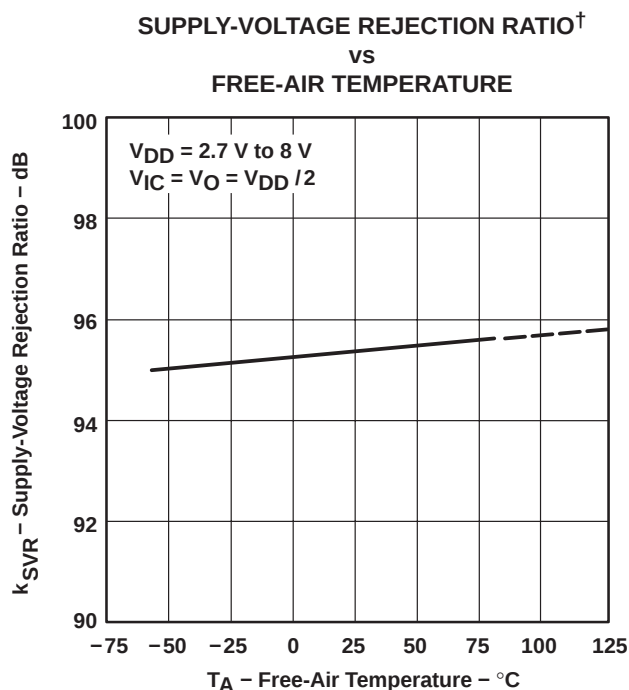


Figure 33

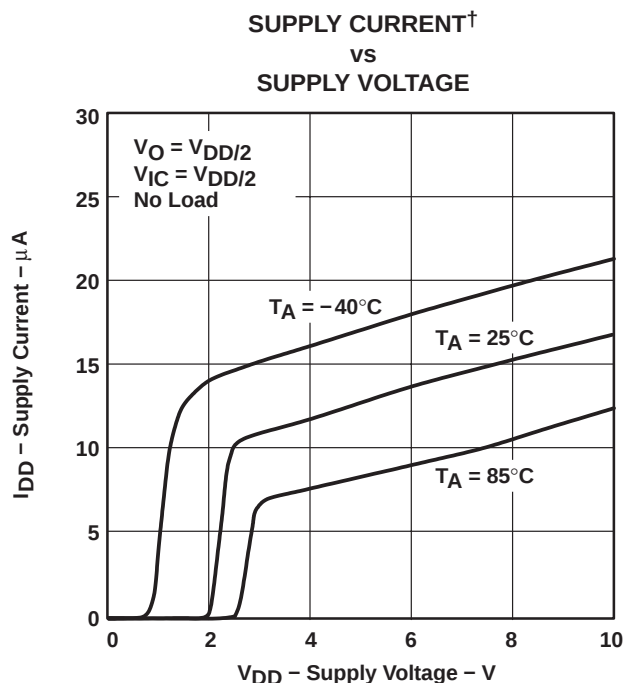


Figure 34

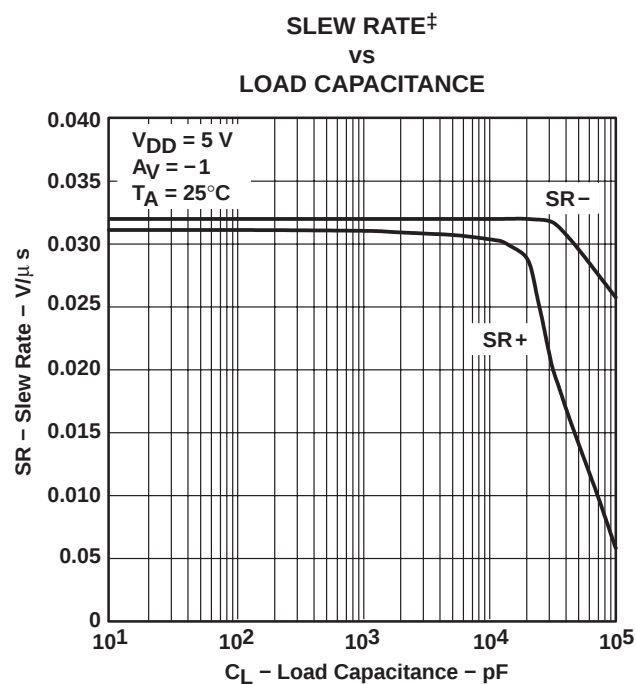


Figure 35

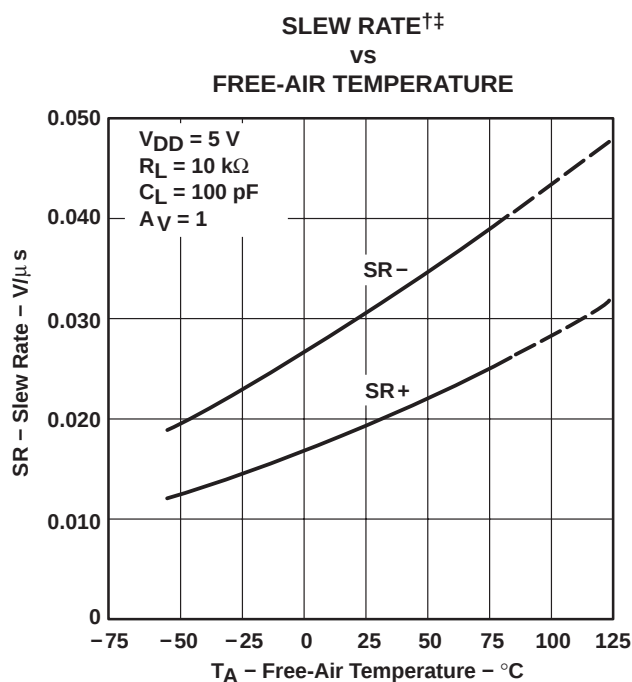


Figure 36

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For all curves where  $V_{DD} = 5 \text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3 \text{ V}$ , all loads are referenced to 1.5 V.

## TYPICAL CHARACTERISTICS

**INVERTING LARGE-SIGNAL PULSE RESPONSE†**

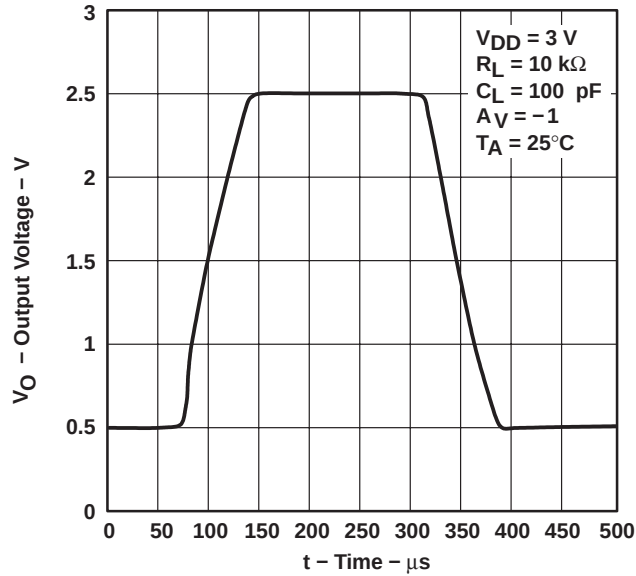


Figure 37

**INVERTING LARGE-SIGNAL PULSE RESPONSE†**

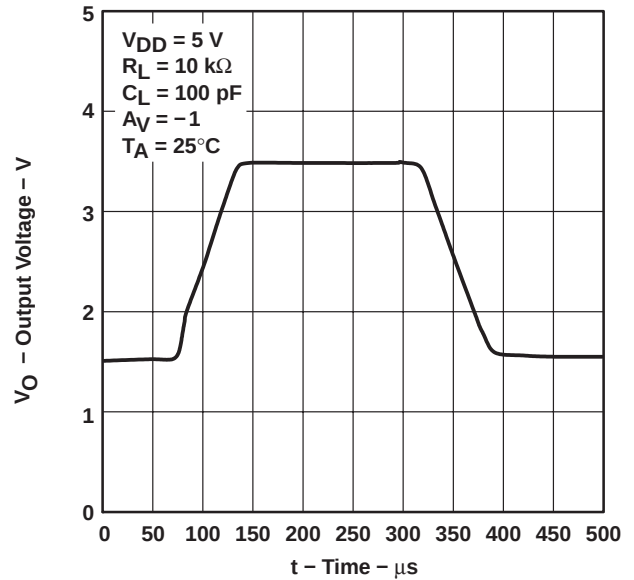


Figure 38

**VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE†**

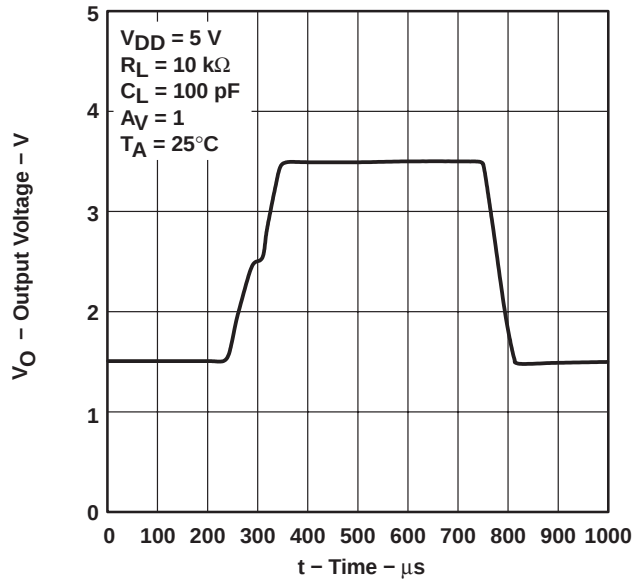


Figure 39

**VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE†**

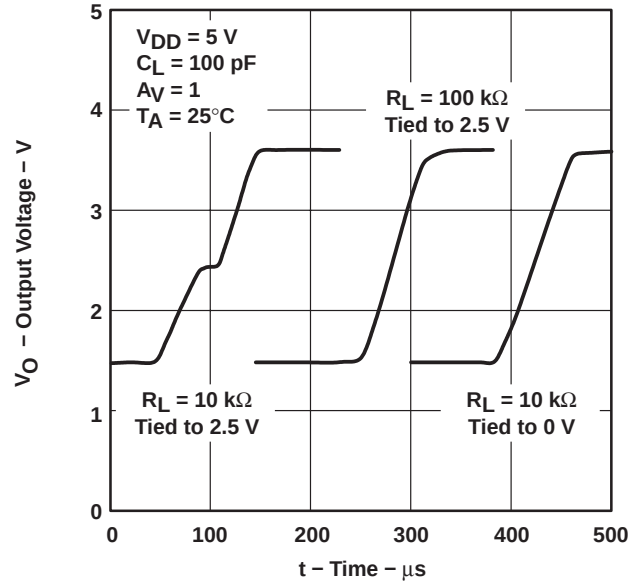
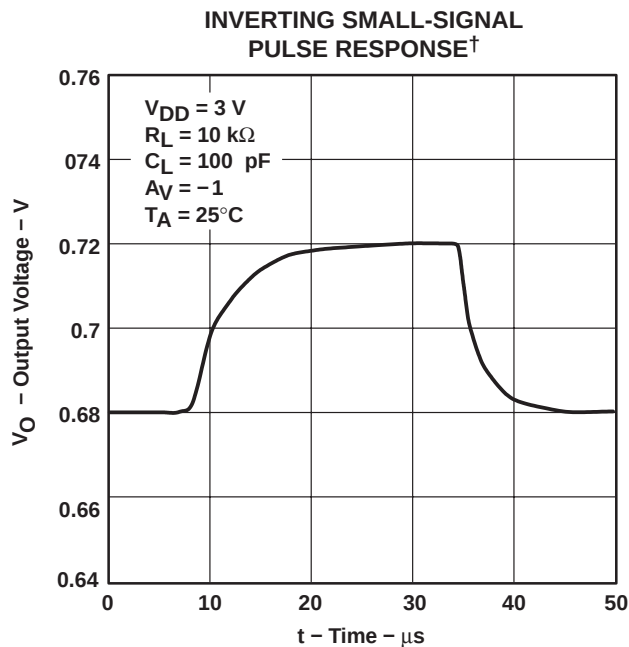


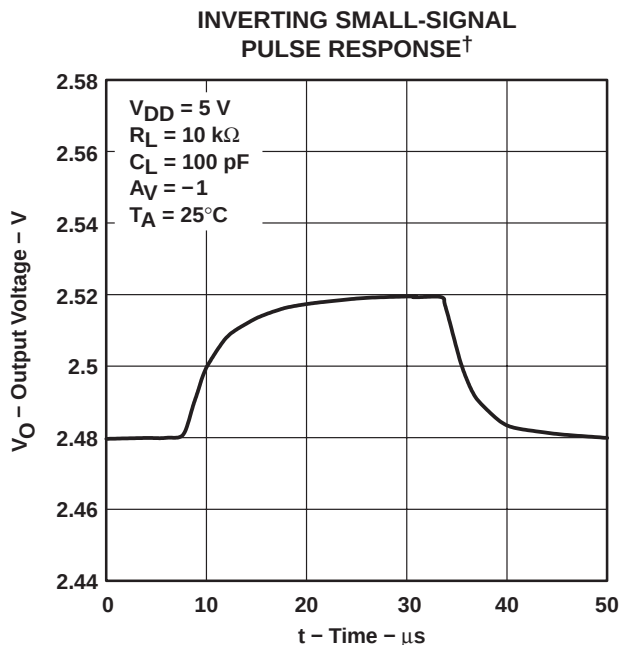
Figure 40

† For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

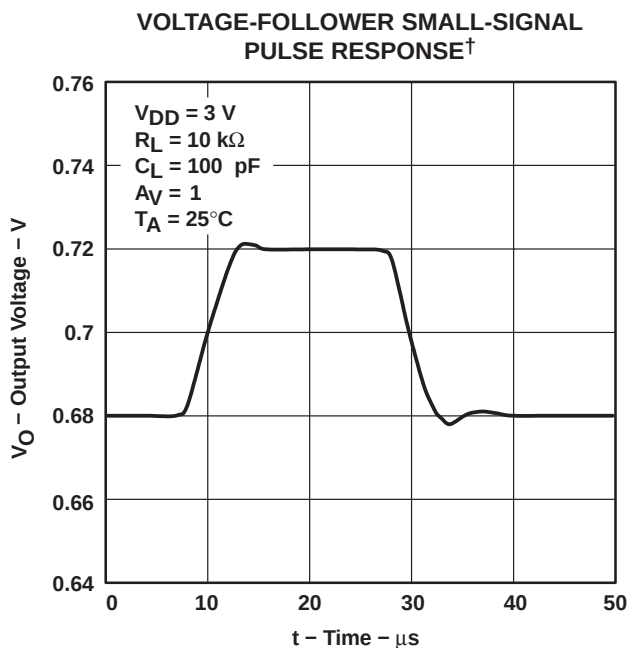
## TYPICAL CHARACTERISTICS



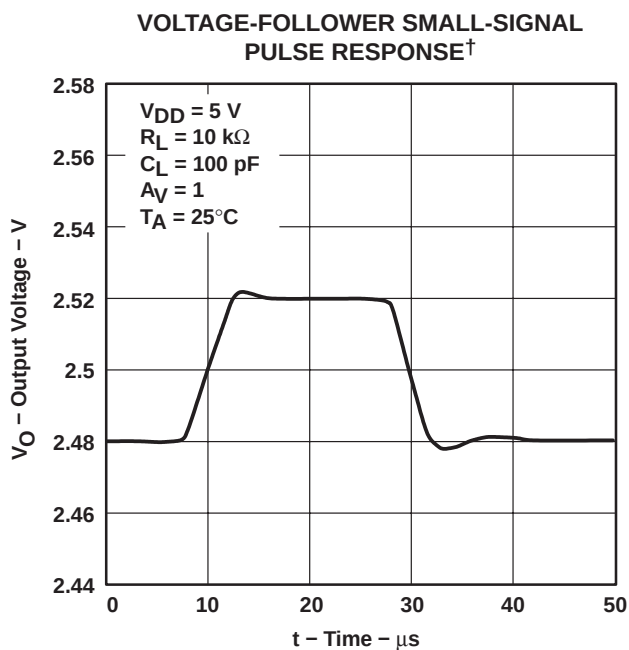
**Figure 41**



**Figure 42**



**Figure 43**



**Figure 44**

† For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

## TYPICAL CHARACTERISTICS

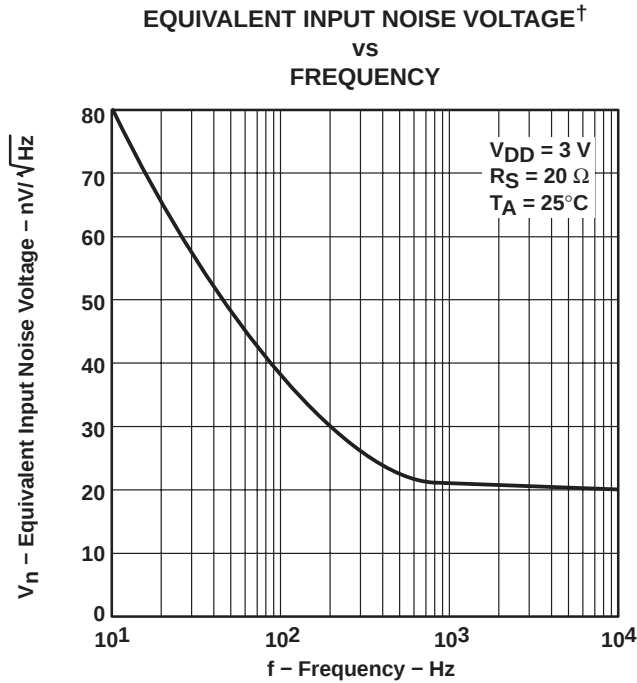


Figure 45

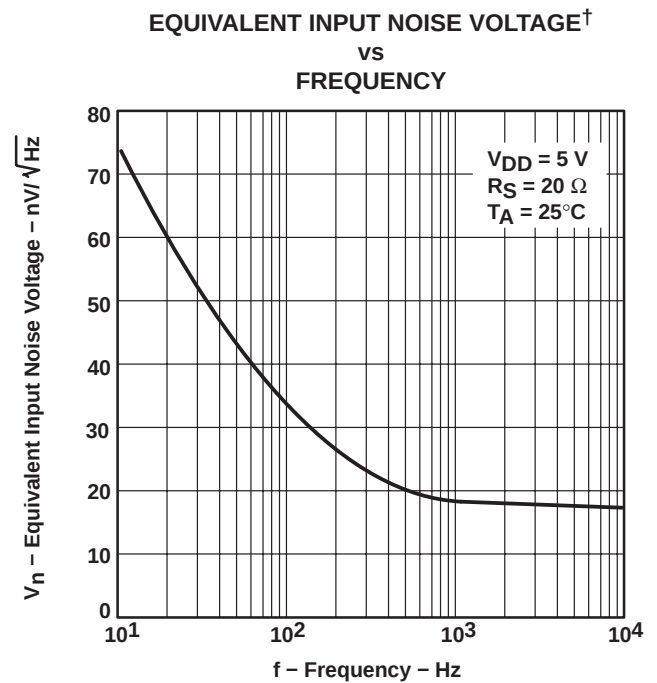


Figure 46

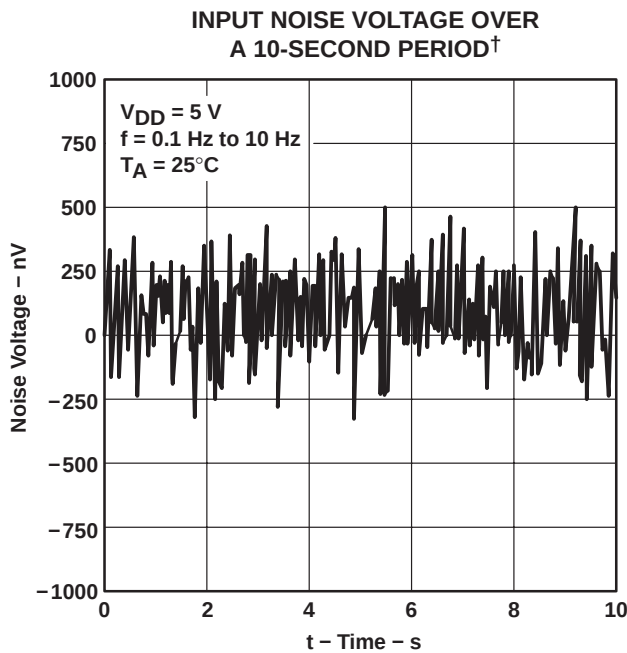


Figure 47

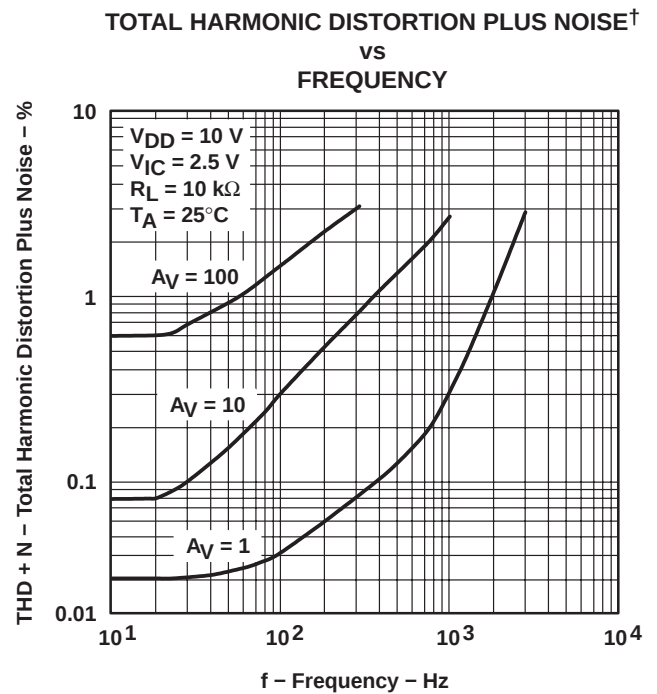


Figure 48

<sup>†</sup> For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

# TLV2211, TLV2211Y

## Advanced LinCMOS™ RAIL-TO-RAIL

### MICROPOWER SINGLE OPERATIONAL AMPLIFIERS

SLOS156E – MAY 1996 – REVISED SEPTEMBER 2006

#### TYPICAL CHARACTERISTICS

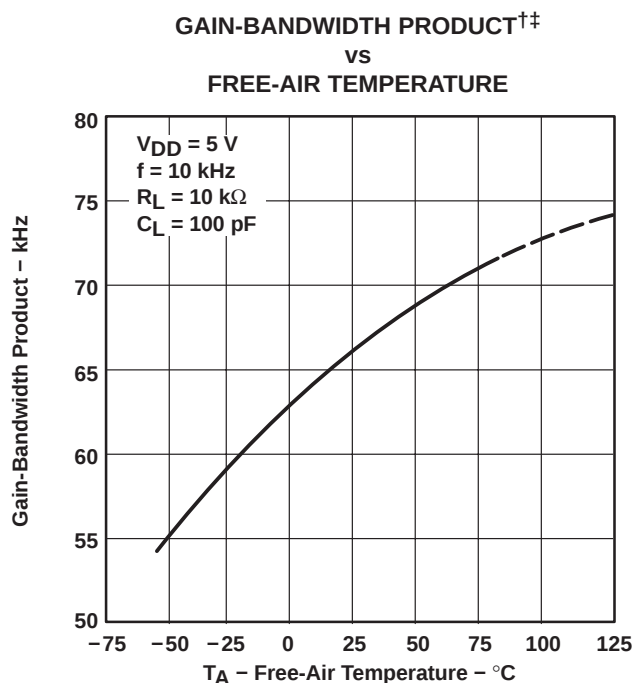


Figure 49

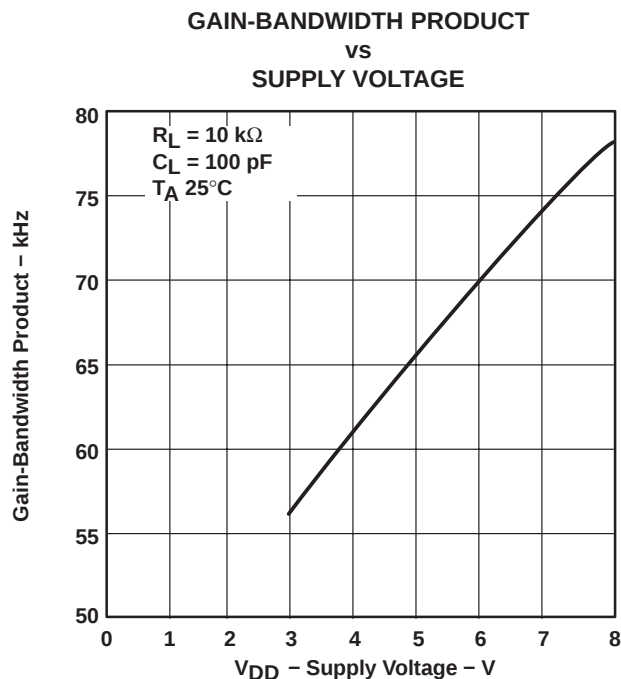


Figure 50

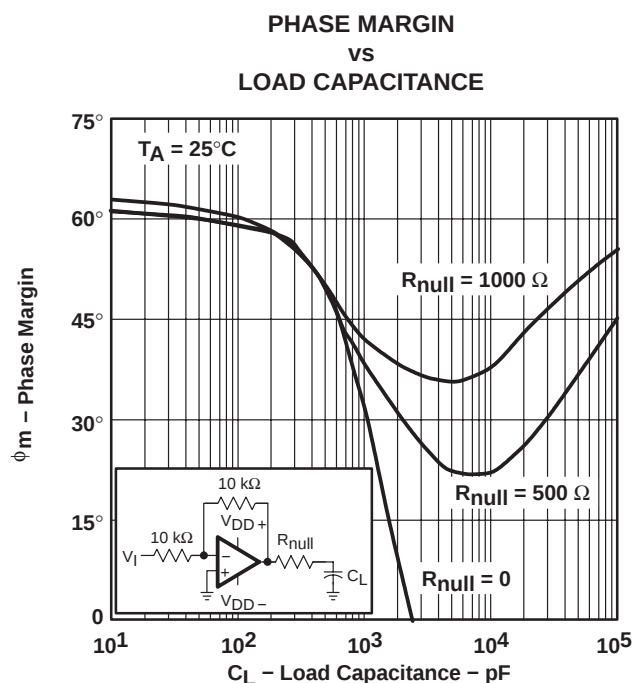


Figure 51

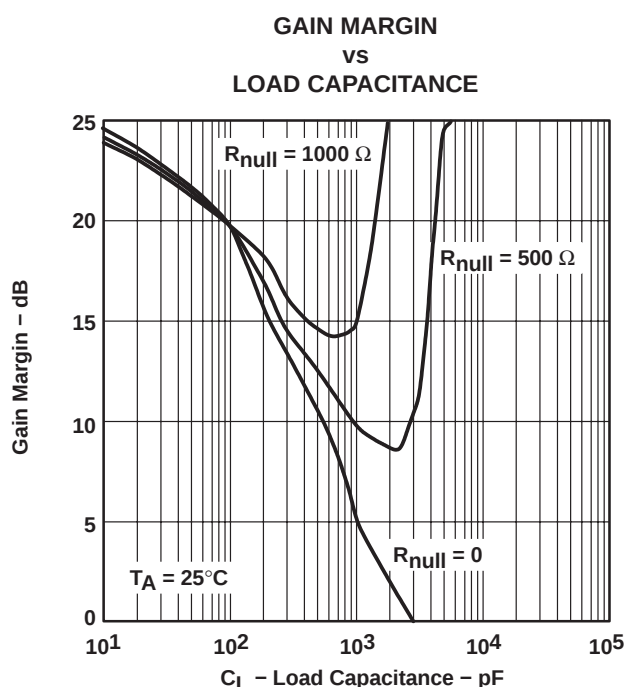


Figure 52

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

## TYPICAL CHARACTERISTICS

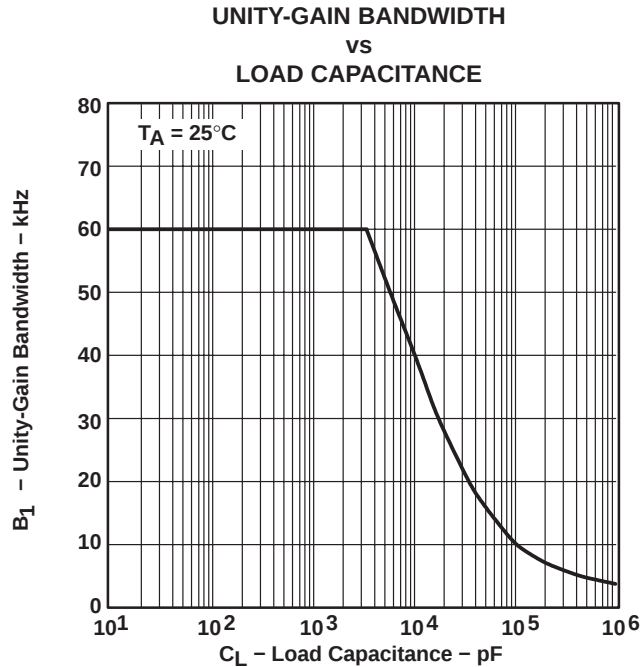


Figure 53

## APPLICATION INFORMATION

### driving large capacitive loads

The TLV2211 is designed to drive larger capacitive loads than most CMOS operational amplifiers. Figures 51 and 52 illustrate its ability to drive loads up to 600 pF while maintaining good gain and phase margins ( $R_{null} = 0$ ).

A smaller series resistor ( $R_{null}$ ) at the output of the device (see Figure 54) improves the gain and phase margins when driving large capacitive loads. Figures 51 and 52 show the effects of adding series resistances of 500  $\Omega$  and 1000  $\Omega$ . The addition of this series resistor has two effects: the first is that it adds a zero to the transfer function and the second is that it reduces the frequency of the pole associated with the output load in the transfer function.

The zero introduced to the transfer function is equal to the series resistance times the load capacitance. To calculate the improvement in phase margin, equation 1 can be used.

$$\Delta\phi_{m1} = \tan^{-1} \left( 2 \times \pi \times \text{UGBW} \times R_{null} \times C_L \right) \quad (1)$$

Where :

$\Delta\phi_{m1}$  = improvement in phase margin

UGBW = unity-gain bandwidth frequency

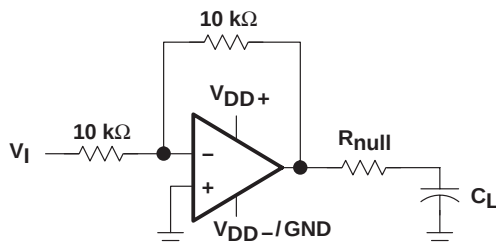
$R_{null}$  = output series resistance

$C_L$  = load capacitance

## APPLICATION INFORMATION

### driving large capacitive loads (continued)

The unity-gain bandwidth (UGBW) frequency decreases as the capacitive load increases (see Figure 54). To use equation 1, UGBW must be approximated from Figure 54.



**Figure 54. Series-Resistance Circuit**

### driving heavy dc loads

The TLV2211 is designed to provide better sinking and sourcing output currents than earlier CMOS rail-to-rail output devices. This device is specified to sink 500  $\mu$ A and source 250  $\mu$ A at  $V_{DD} = 3$  V and  $V_{DD} = 5$  V at a maximum quiescent  $I_{DD}$  of 25  $\mu$ A. This provides a greater than 90% power efficiency.

When driving heavy dc loads, such as 10 kΩ, the positive edge can experience some distortion under slewing conditions. This condition can be seen in Figure 39. This condition is affected by three factors:

- Where the load is referenced. When the load is referenced to either rail, this condition does not occur. The distortion occurs only when the output signal swings through the point where the load is referenced. Figure 40 illustrates two 10-kΩ load conditions. The first load condition shows the distortion seen for a 10-kΩ load tied to 2.5 V. The third load condition shows no distortion for a 10-kΩ load tied to 0 V.
- Load resistance. As the load resistance increases, the distortion seen on the output decreases. Figure 40 illustrates the difference seen on the output for a 10-kΩ load and a 100-kΩ load with both tied to 2.5 V.
- Input signal edge rate. Faster input edge rates for a step input result in more distortion than with slower input edge rates.

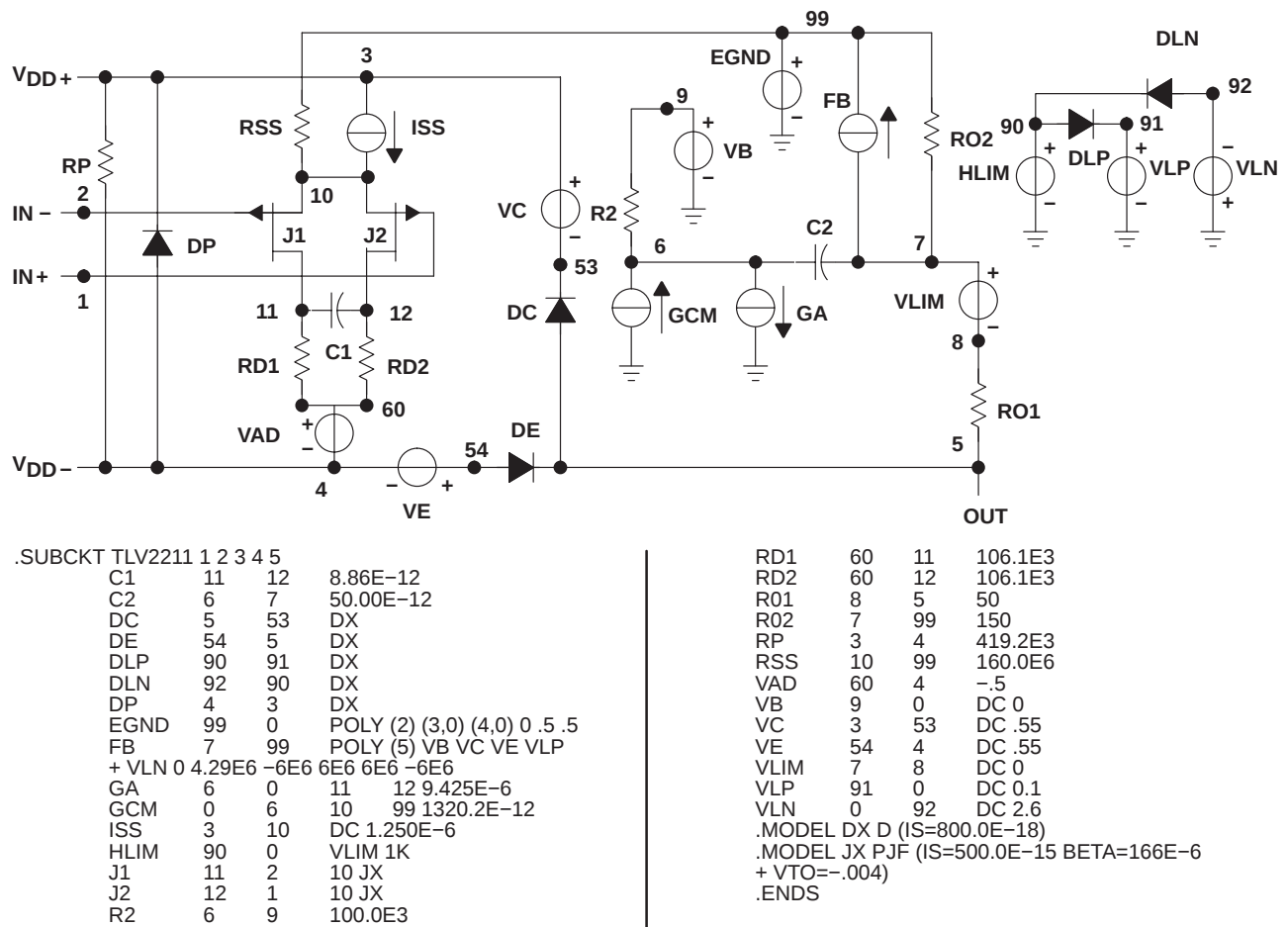
## APPLICATION INFORMATION

### macromodel information

Macromodel information provided was derived using Microsim *Parts*™, the model generation software used with Microsim *PSpice*™. The Boyle macromodel (see Note 6) and subcircuit in Figure 54 are generated using the TLV2211 typical electrical and operating characteristics at  $T_A = 25^\circ\text{C}$ . Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 6: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).



**Figure 55. Boyle Macromodel and Subcircuit**

*PSpice* and *Parts* are trademark of MicroSim Corporation.

Macromodels, simulation models, or other models provided by TI, directly or indirectly, are not warranted by TI as fully representing all of the specification and operating characteristics of the semiconductor product to which the model relates.



## PACKAGING INFORMATION

| Orderable part number        | Status<br>(1) | Material type<br>(2) | Package   Pins   | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|------------------------------|---------------|----------------------|------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| TLV2211CDBVR                 | Obsolete      | Production           | SOT-23 (DBV)   5 | -                     | -           | Call TI                              | Call TI                           | 0 to 70      | VACC                |
| <a href="#">TLV2211CDBVT</a> | Obsolete      | Production           | SOT-23 (DBV)   5 | -                     | -           | Call TI                              | Call TI                           | 0 to 70      | VACC                |
| <a href="#">TLV2211IDBVR</a> | Active        | Production           | SOT-23 (DBV)   5 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | VACI                |
| TLV2211IDBVR.A               | Active        | Production           | SOT-23 (DBV)   5 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | VACI                |
| TLV2211IDBVRG4               | Active        | Production           | SOT-23 (DBV)   5 | 3000   LARGE T&R      | -           | Call TI                              | Call TI                           | -40 to 85    |                     |
| <a href="#">TLV2211IDBVT</a> | Active        | Production           | SOT-23 (DBV)   5 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | VACI                |
| TLV2211IDBVT.A               | Active        | Production           | SOT-23 (DBV)   5 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | VACI                |
| TLV2211IDBVTG4               | Active        | Production           | SOT-23 (DBV)   5 | 250   SMALL T&R       | -           | Call TI                              | Call TI                           | -40 to 85    |                     |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TLV2211IDBVR | SOT-23       | DBV             | 5    | 3000 | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TLV2211IDBVT | SOT-23       | DBV             | 5    | 250  | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TLV2211IDBVR | SOT-23       | DBV             | 5    | 3000 | 180.0       | 180.0      | 18.0        |
| TLV2211IDBVT | SOT-23       | DBV             | 5    | 250  | 180.0       | 180.0      | 18.0        |



## SOT-23 - 1.45 mm max height

## SMALL OUTLINE TRANSISTOR

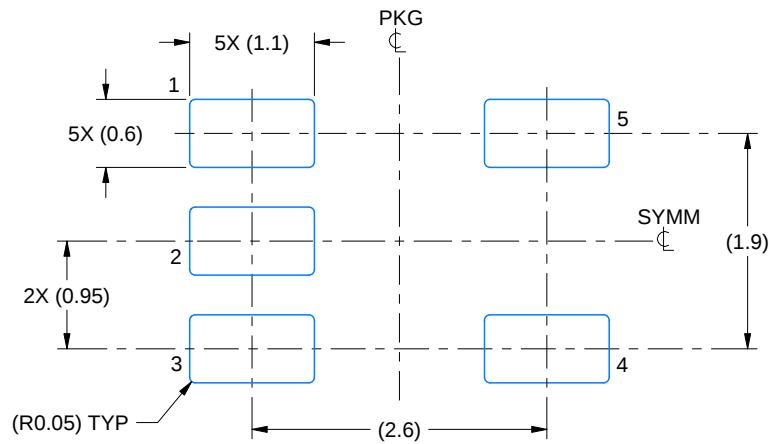


1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

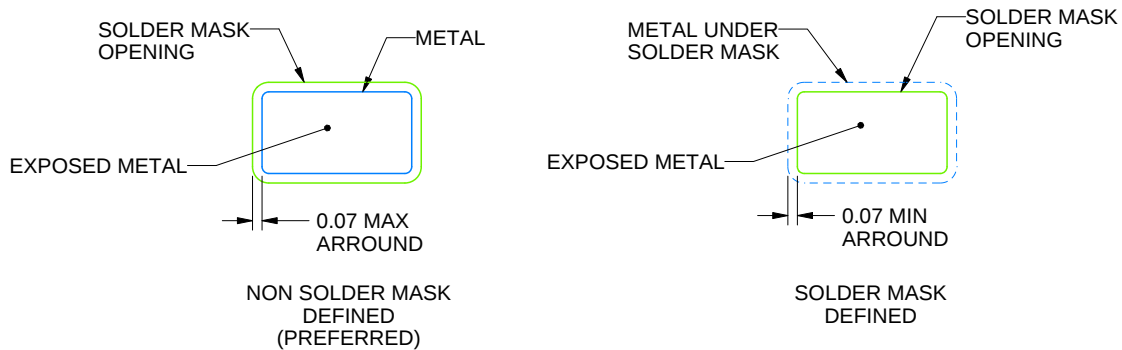
**DBV0005A**

**SOT-23 - 1.45 mm max height**

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:15X



## SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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